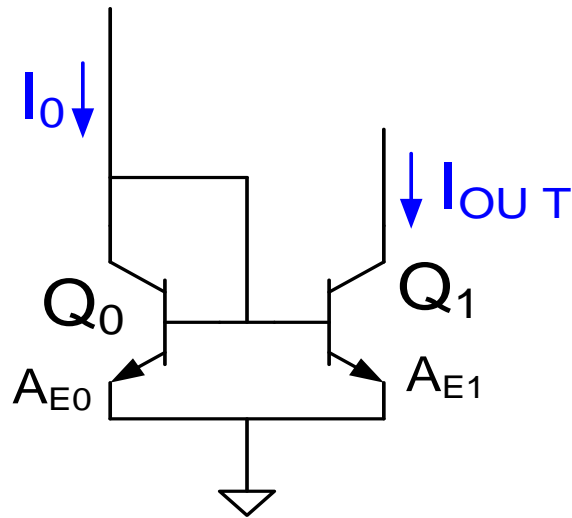


# EE 330

## Lecture 35

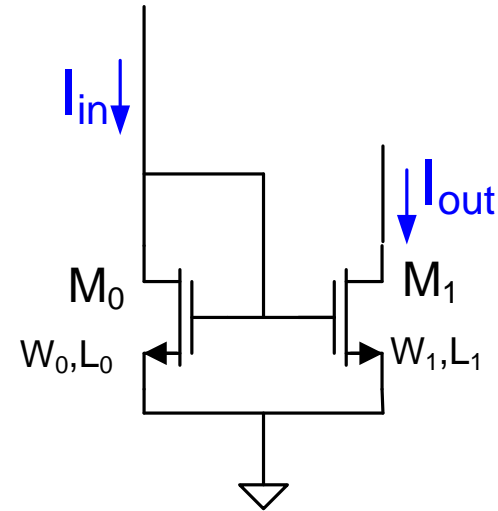
- High Gain Amplifiers
- Cascode and Cascade Configurations
- Biasing

# Current Sources/Mirrors Summary



**npn Current Mirror**

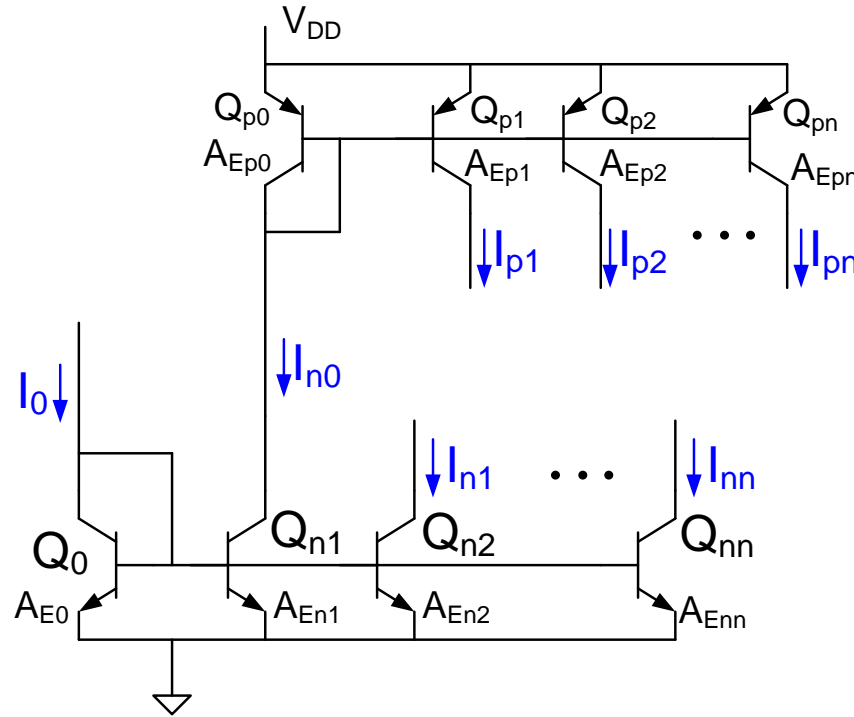
$$I_{out} = \left[ \frac{A_{E1}}{A_{E0}} \right] I_{in}$$



**n-channel Current Mirror**

$$I_{out} = \left[ \frac{W_1}{W_0} \frac{L_0}{L_1} \right] I_{in}$$

# Current Sources/Mirrors

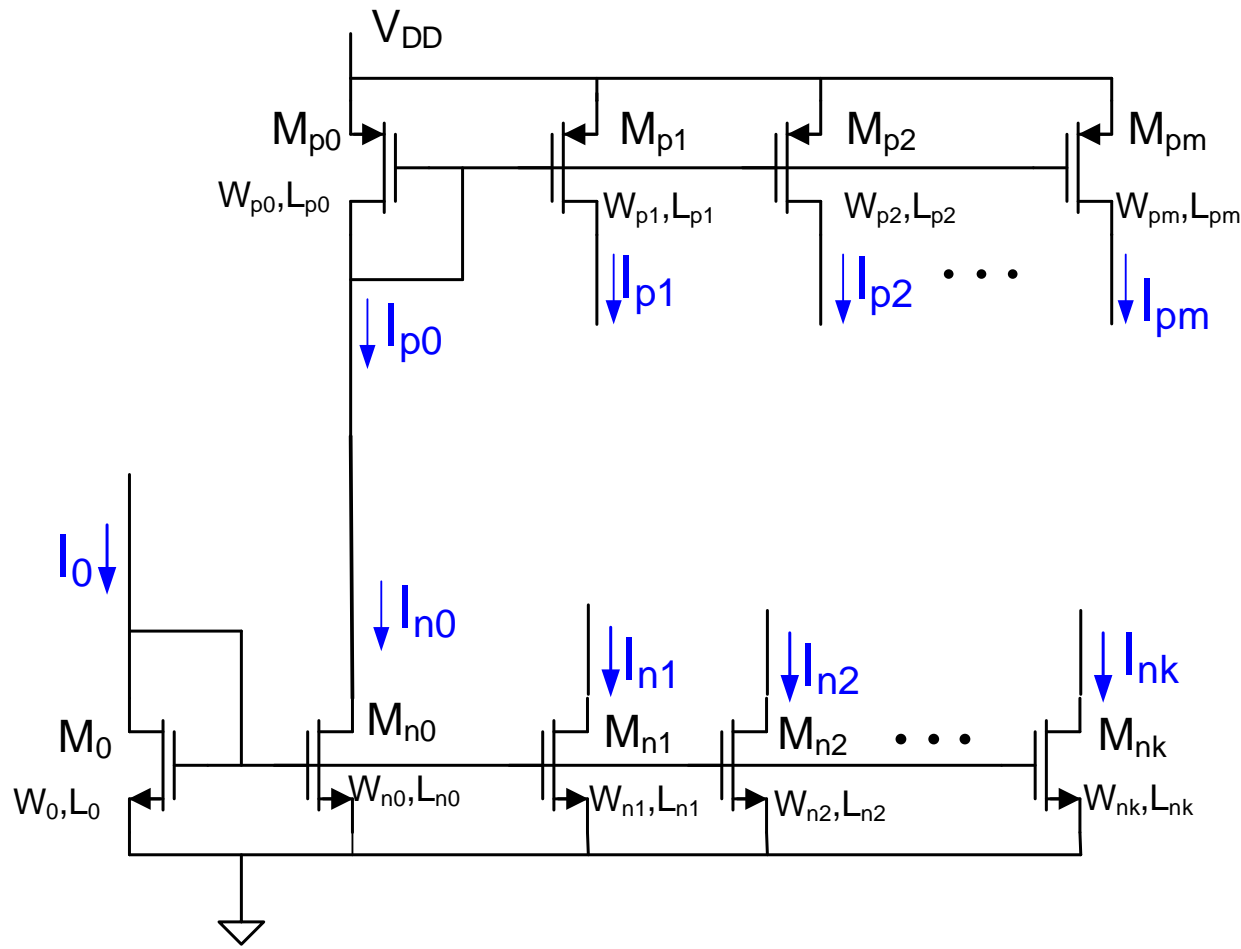


**Multiple-Output Bipolar Current Source and Sink**

$$I_{nk} = \left[ \frac{A_{Enk}}{A_{E0}} \right] I_0 \qquad I_{pk} = \left[ \frac{A_{En1}}{A_{E0}} \right] \left[ \frac{A_{Epk}}{A_{Ep0}} \right] I_0$$

# Current Sources/Mirrors

multiple sourcing and sinking current outputs



$$I_{pj} = \left[ \frac{W_{pj}}{L_{pj}} \cdot \frac{L_{p0}}{W_{p0}} \right] M I_0$$

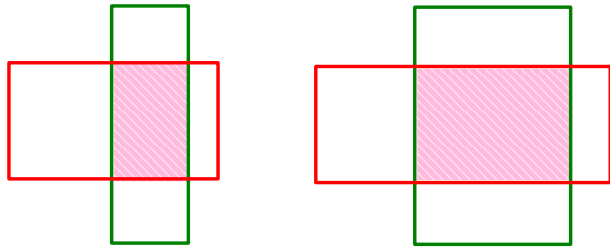
$$M = \left[ \frac{W_{n0}}{L_{n0j}} \cdot \frac{L_0}{W_0} \right]$$

$$I_{nj} = \left[ \frac{W_{nj}}{L_{nj}} \cdot \frac{L_0}{W_0} \right] I_0$$

$m$  and  $k$  may be different  
Often  $M=1$

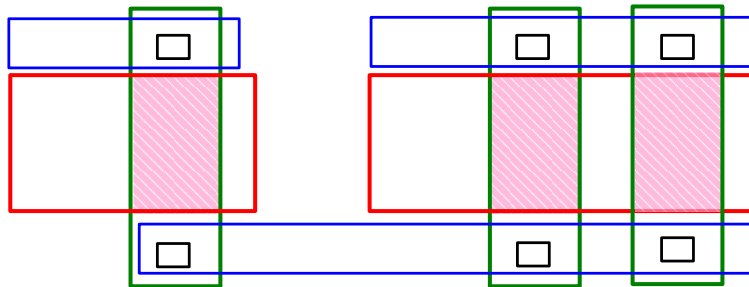
# Layout of Current Mirrors

Example with  $M = 2$



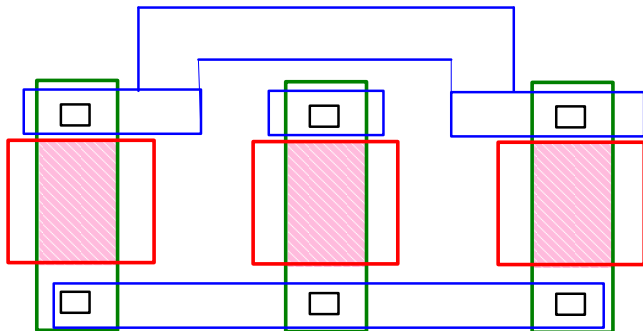
**Standard layout**

$$M = \left[ \frac{W_2}{W_1} \frac{L_1}{L_2} \right]$$



**Better Layout**

$$M = \left[ \frac{2W_1 + 4\Delta W}{W_1 + 2\Delta W} \cdot \frac{L_1 + 2\Delta L}{L_1 + 2\Delta L} \right] = 2$$



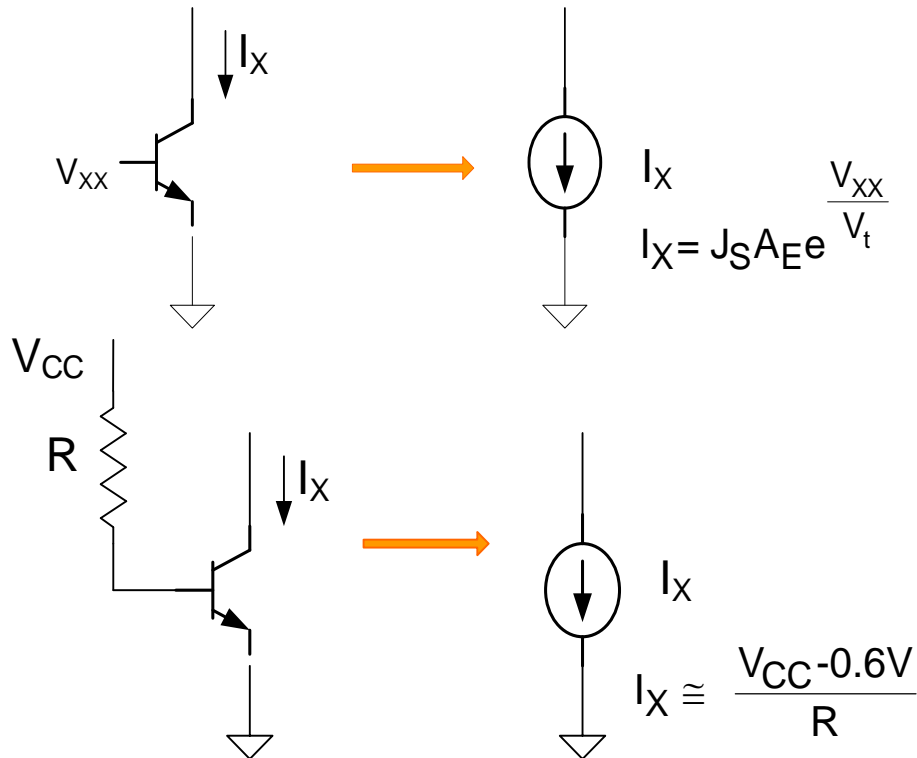
**Even Better Layout**

$$M = \left[ \frac{2W_1 + 4\Delta W}{W_1 + 2\Delta W} \cdot \frac{L_1 + 2\Delta L}{L_1 + 2\Delta L} \right] = 2$$

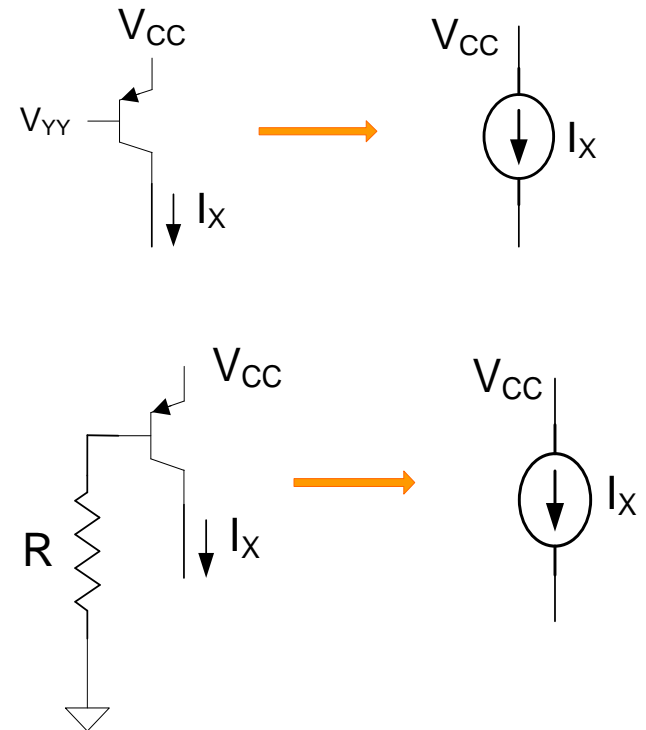
**This is termed a common-centroid layout**

# Basic Current Sources and Sinks

## Basic Bipolar Current Sinks

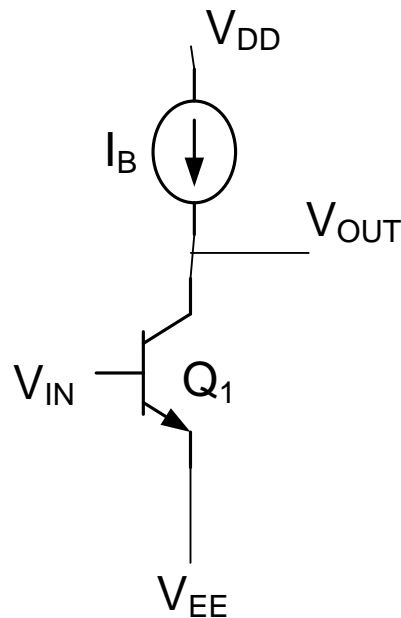


## Basic Bipolar Current Sources



- Very practical methods for biasing the BJTs (or MOSFETs) can be used
- Current Mirrors often used for generating sourcing and sinking currents
- Can think of biasing transistors with  $V_{XX}$  and  $V_{YY}$  in these current sources

# High-gain amplifier



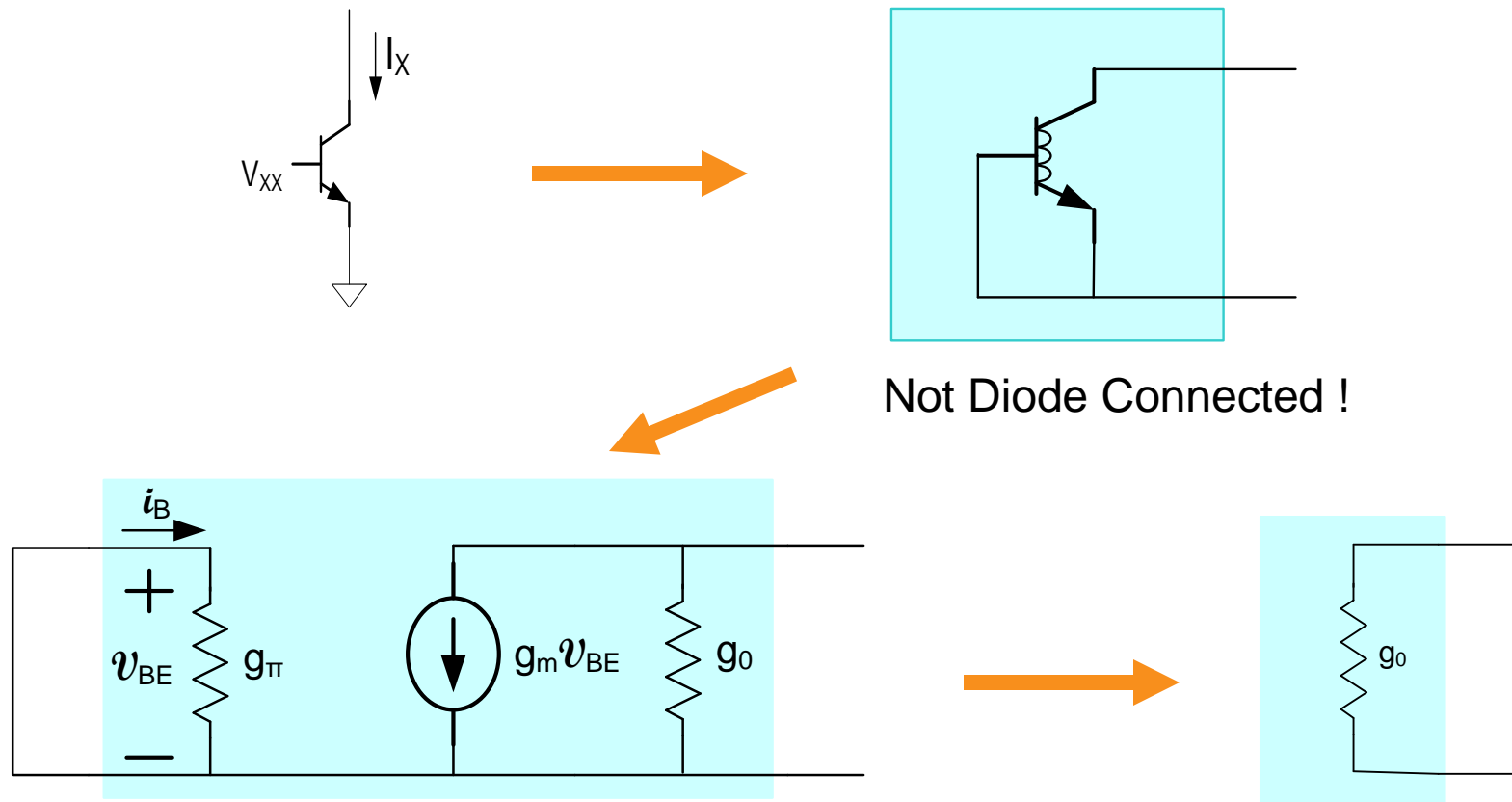
$$A_V \cong -8000$$

How can we build the current source?

→ What is the small-signal model of an actual current source?

# Basic Current Sources and Sinks

## Small-signal Model of BJT Current Sinks and Sources

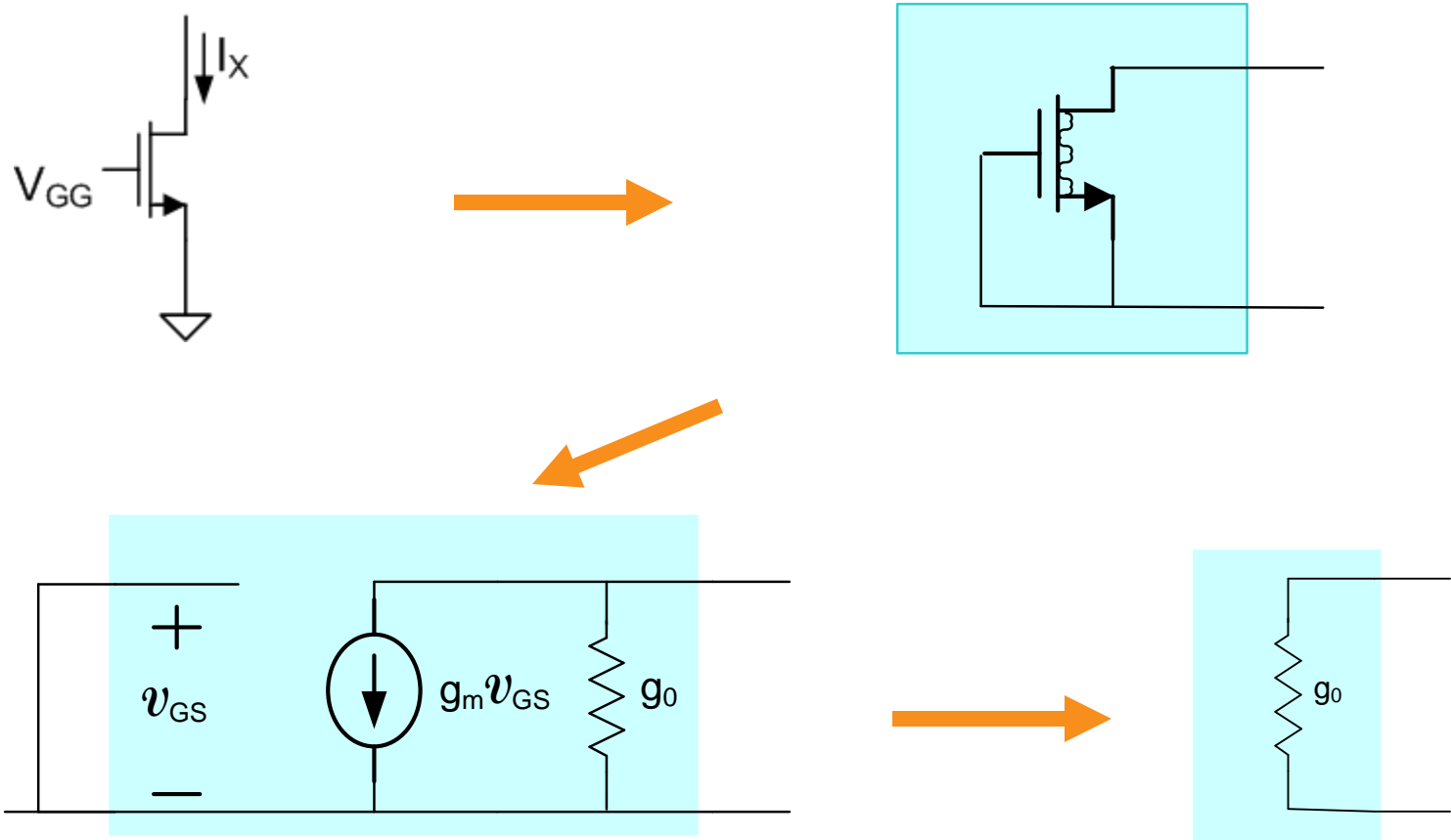


**Small-signal model of all other BJT Sinks and Sources introduced so far are the same**



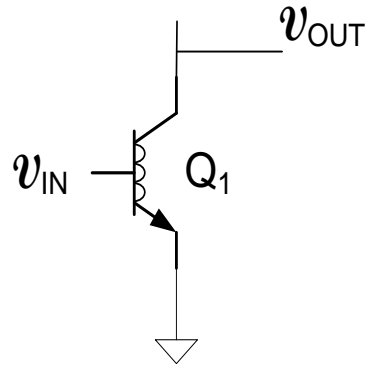
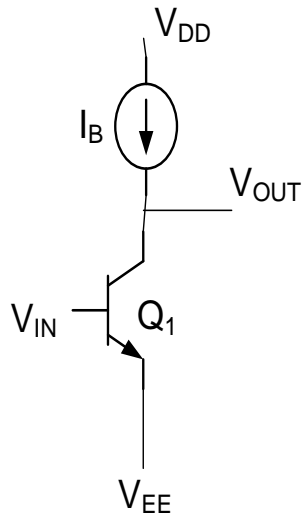
# Basic Current Sources and Sinks

## Small-signal Model of MOS Current Sinks and Sources

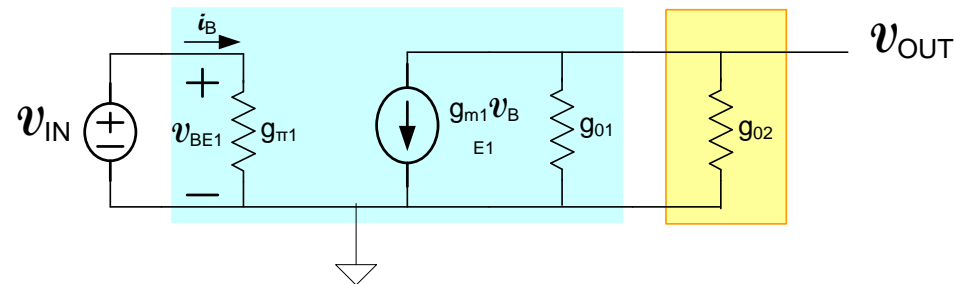
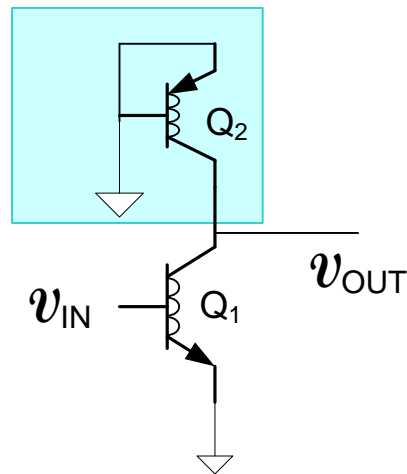
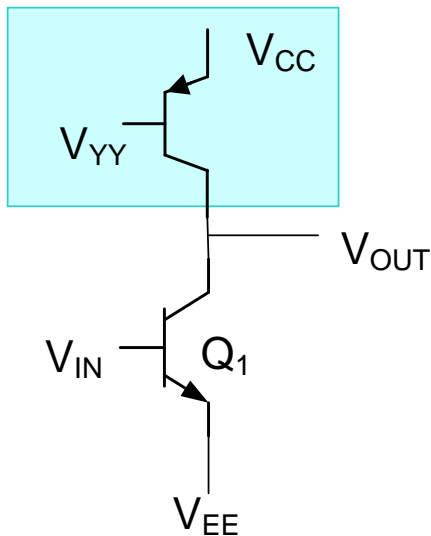


**Small-signal model of all other MOS Sinks and Sources introduced thus far are the same**

# High-gain amplifier

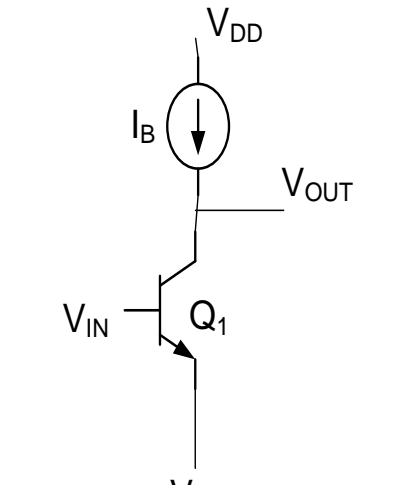


$$A_V = \frac{-g_m}{g_o}$$



$$A_V = \frac{-g_{m1}}{g_{o1} + g_{o2}} \approx \frac{-g_{m1}}{2g_{o1}}$$

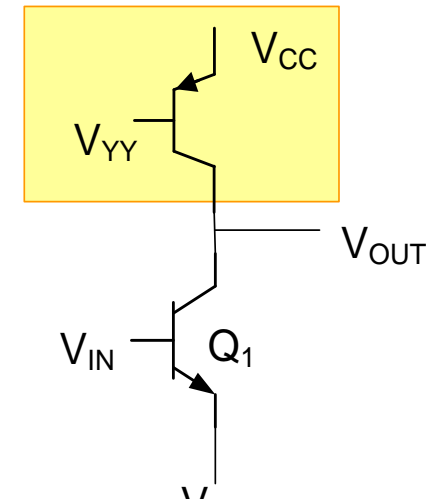
# High-gain amplifier



Circuit diagram of a common-emitter amplifier. The input signal  $V_{IN}$  is applied to the base of transistor  $Q_1$ . The emitter is connected to  $V_{EE}$ . The collector is connected to  $V_{DD}$  through a nonideal current source  $I_B$ . The output voltage  $V_{OUT}$  is taken from the collector. The voltage gain is given by:

$$A_V = \frac{-g_m}{g_0} = -8000$$

$$\frac{g_m}{g_0} = \frac{g_{m1}}{g_{01}} = \frac{V_{AF}}{V_t} \cong 8000$$



Circuit diagram of a common-emitter amplifier with an ideal current source load. The input signal  $V_{IN}$  is applied to the base of transistor  $Q_1$ . The emitter is connected to  $V_{EE}$ . The collector is connected to  $V_{CC}$  through an ideal current source  $V_{YY}$ . The output voltage  $V_{OUT}$  is taken from the collector. The voltage gain is given by:

$$A_V \cong \frac{-g_{m1}}{2g_{01}} = -4000$$

- Nonideal current source decreased the gain by a factor of 2
- But the voltage gain is still quite large (-4000)

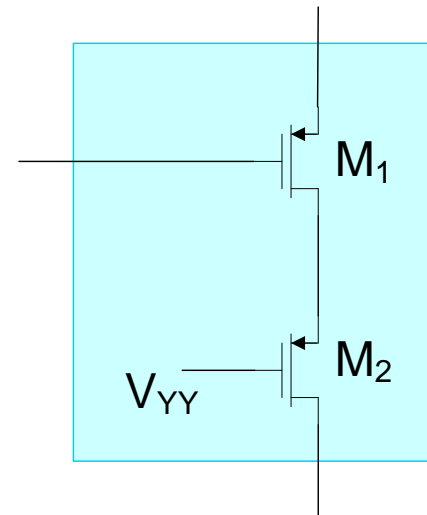
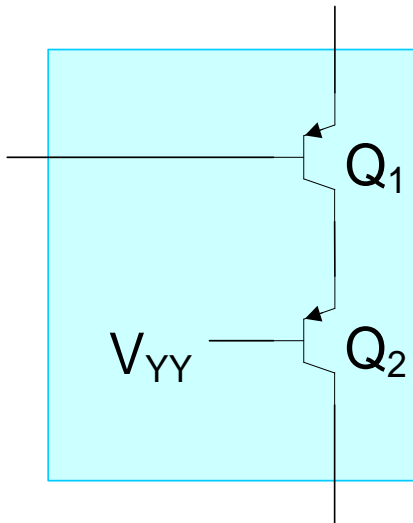
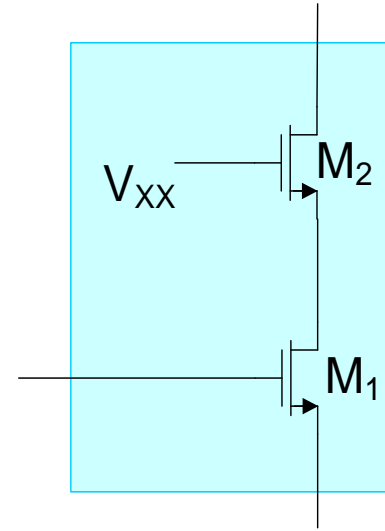
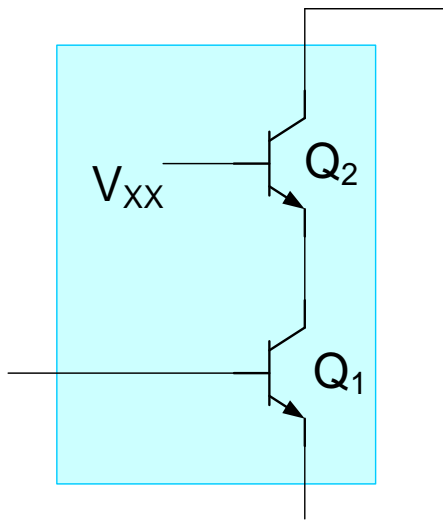
**Can the gain be made even larger?**

# High-gain amplifier

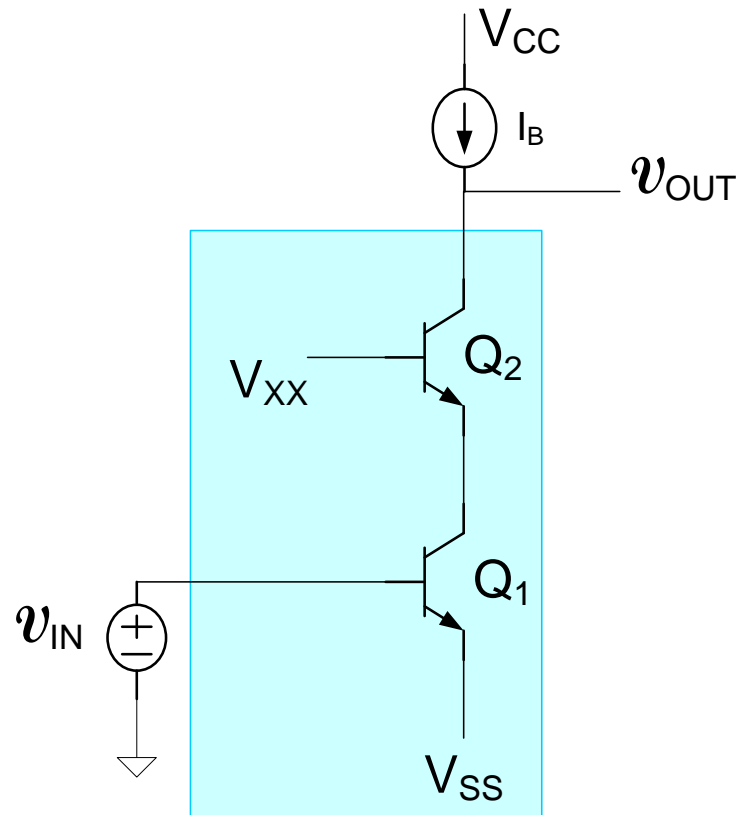
Can the gain be made even larger?

Discuss

## The Cascode Configuration



# The Cascode Amplifier (consider npn BJT version)



**Discuss**

- Actually a cascade of a CE stage followed by a CB stage but usually viewed as a “single-stage” structure
- Cascode structure is widely used

# Basic Amplifier Structures

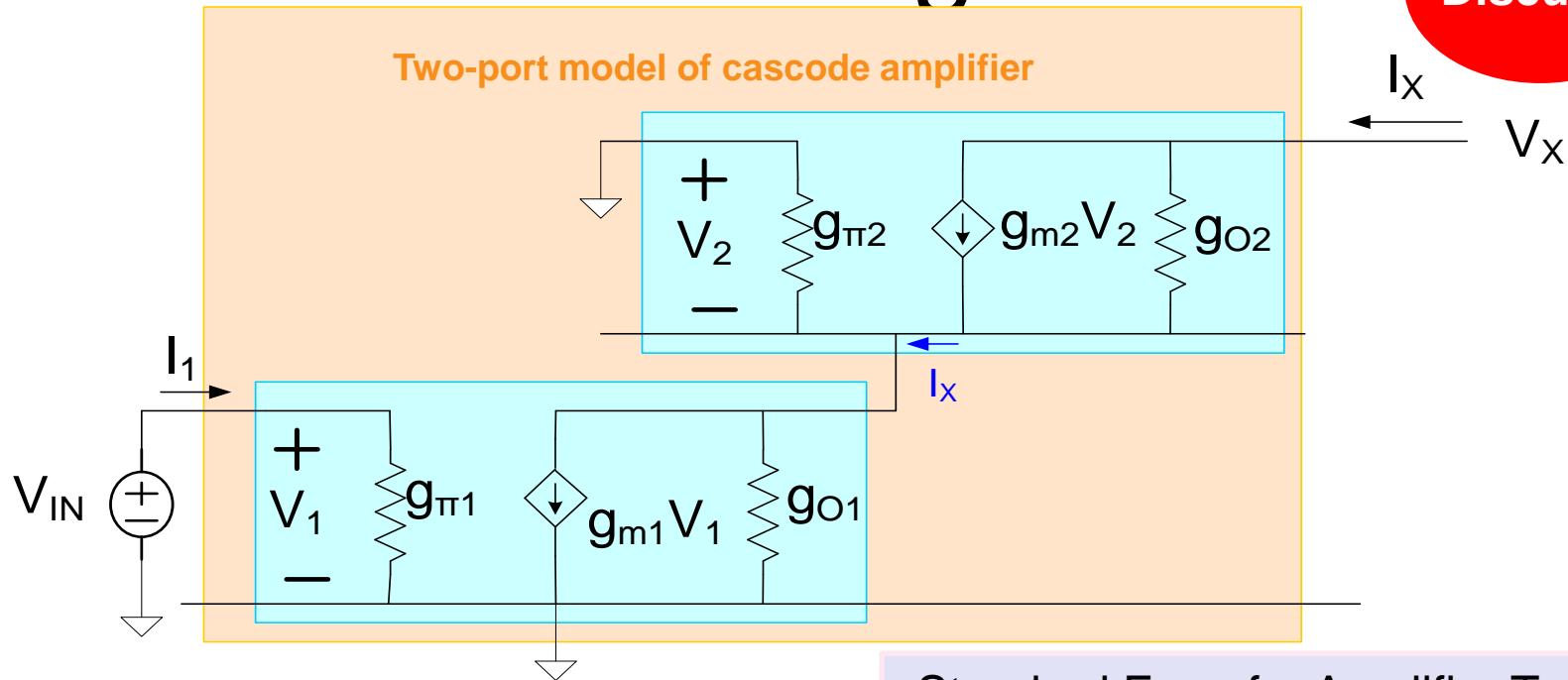
Discuss

1. Common Emitter/Common Source
2. Common Collector/Common Drain
3. Common Base/Common Gate
4. Common Emitter with  $R_E$ / Common Source with  $R_S$
- 5. Cascode (actually CE:CB or CS:CD cascade)
6. Darlington (special CE:CE or CS:CS cascade)

The first 4 are most popular

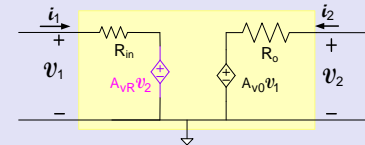
# Cascode Configuration

Discuss



$$\left. \begin{aligned} (V_X + V_2)g_{o2} + V_2g_{m2} &= I_X \\ V_1g_{m1} - V_2(g_{o1} + g_{\pi2}) &= I_X \end{aligned} \right\}$$

Standard Form for Amplifier Two-Port



$$\begin{aligned} v_1 &= i_1 R_{IN} + A_{VR} v_2 \\ v_2 &= i_2 R_O + A_{V0} v_1 \end{aligned}$$

Observing  $V_1 = V_{IN}$  and eliminating  $V_2$  between these two equations, we obtain

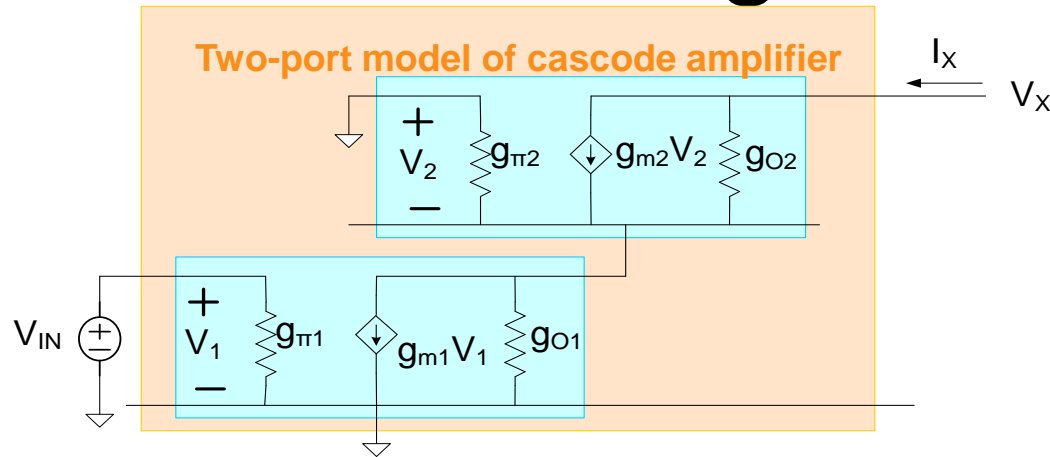
$$V_{IN} = I_1 \cdot \frac{1}{g_{\pi1}}$$

and

$$V_X = I_X \cdot \left[ \frac{g_{o1} + g_{o2} + g_{\pi2} + g_{m2}}{g_{o2}(g_{o1} + g_{\pi2})} \right] - V_{IN} \cdot \left[ \frac{g_{m1}(g_{o2} + g_{m2})}{g_{o2}(g_{\pi2} + g_{o1})} \right]$$

# Cascode Configuration

Discuss



$$V_X = I_X \cdot \left[ \frac{g_{o1} + g_{o2} + g_{\pi 2} + g_{m2}}{g_{o2}(g_{o1} + g_{\pi 2})} \right] - V_{IN} \cdot \left[ \frac{g_{m1}(g_{o2} + g_{m2})}{g_{o2}(g_{\pi 2} + g_{o1})} \right]$$

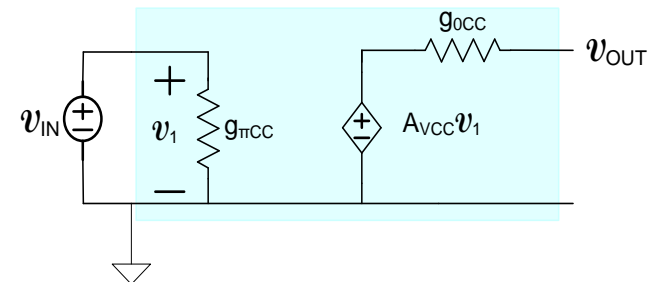
$$V_{IN} = I_X \cdot \frac{1}{g_{\pi 1}}$$

It thus follows for the npn bipolar structure that :

$$A_{VCC} = - \left[ \frac{g_{m1}(g_{o2} + g_{m2})}{g_{o2}(g_{\pi 2} + g_{o1})} \right] \cong - \left[ \frac{g_{m1}g_{m2}}{g_{o2}g_{\pi 2}} \right]$$

$$g_{oCC} = \left[ \frac{g_{o2}(g_{o1} + g_{\pi 2})}{g_{o1} + g_{o2} + g_{\pi 2} + g_{m2}} \right] \cong \left[ \frac{g_{o2}g_{\pi 2}}{g_{m2}} \right]$$

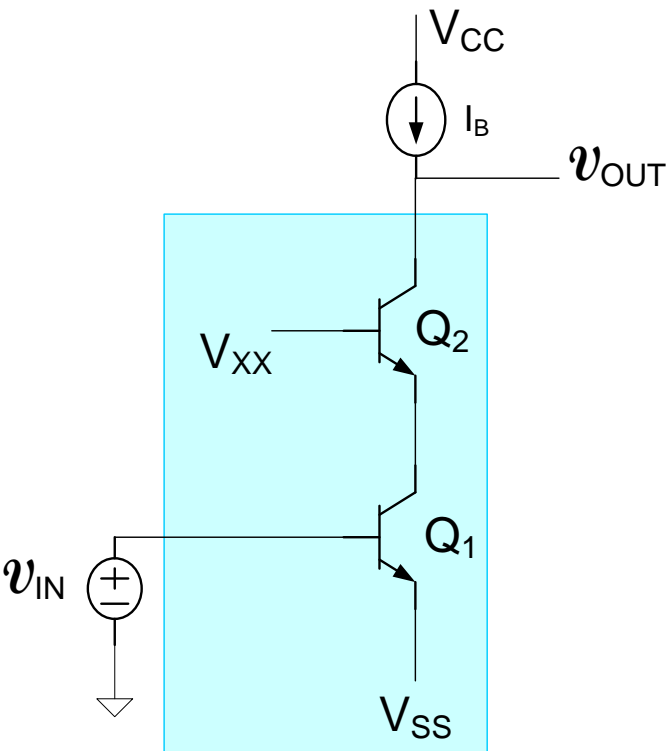
$$g_{\pi CC} = g_{\pi 1}$$





# Cascode Configuration

Discuss



$$A_{V_{CC}} \cong - \left[ \frac{g_{m1} g_{m2}}{g_{o2} g_{\pi 2}} \right]$$

$$g_{oCC} \cong \left[ \frac{g_{o2} g_{\pi 2}}{g_{m2}} \right]$$

$$g_{\pi CC} = g_{\pi 1}$$

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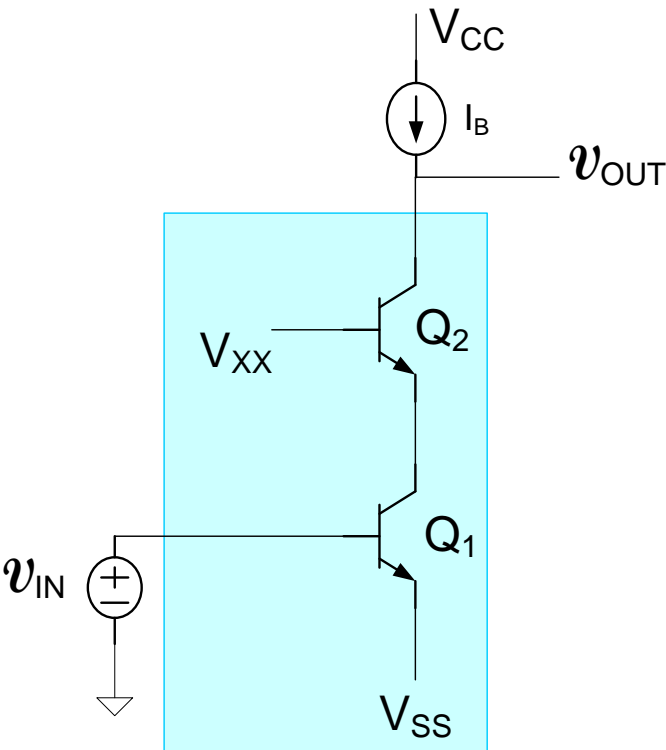

$$A_{V_{CC}} \cong - \left[ \frac{g_{m1}}{g_{o2}} \beta \right] \cong - \left[ \frac{g_{m1}}{g_{o1}} \right] \beta$$

$$g_{oCC} \cong \frac{g_{o1}}{\beta}$$

- Voltage gain is a factor of  $\beta$  larger than that of the CE amplifier with current source load
- Output impedance is a factor of  $\beta$  larger than that of the CE amplifier

# Cascode Configuration

Discuss



$$A_{V_{CC}} \cong - \left[ \frac{g_{m1}}{g_{o2}} \beta \right] \cong - \left[ \frac{g_{m1}}{g_{o1}} \right] \beta$$

$$g_{oCC} \cong \frac{g_{o2}}{\beta}$$

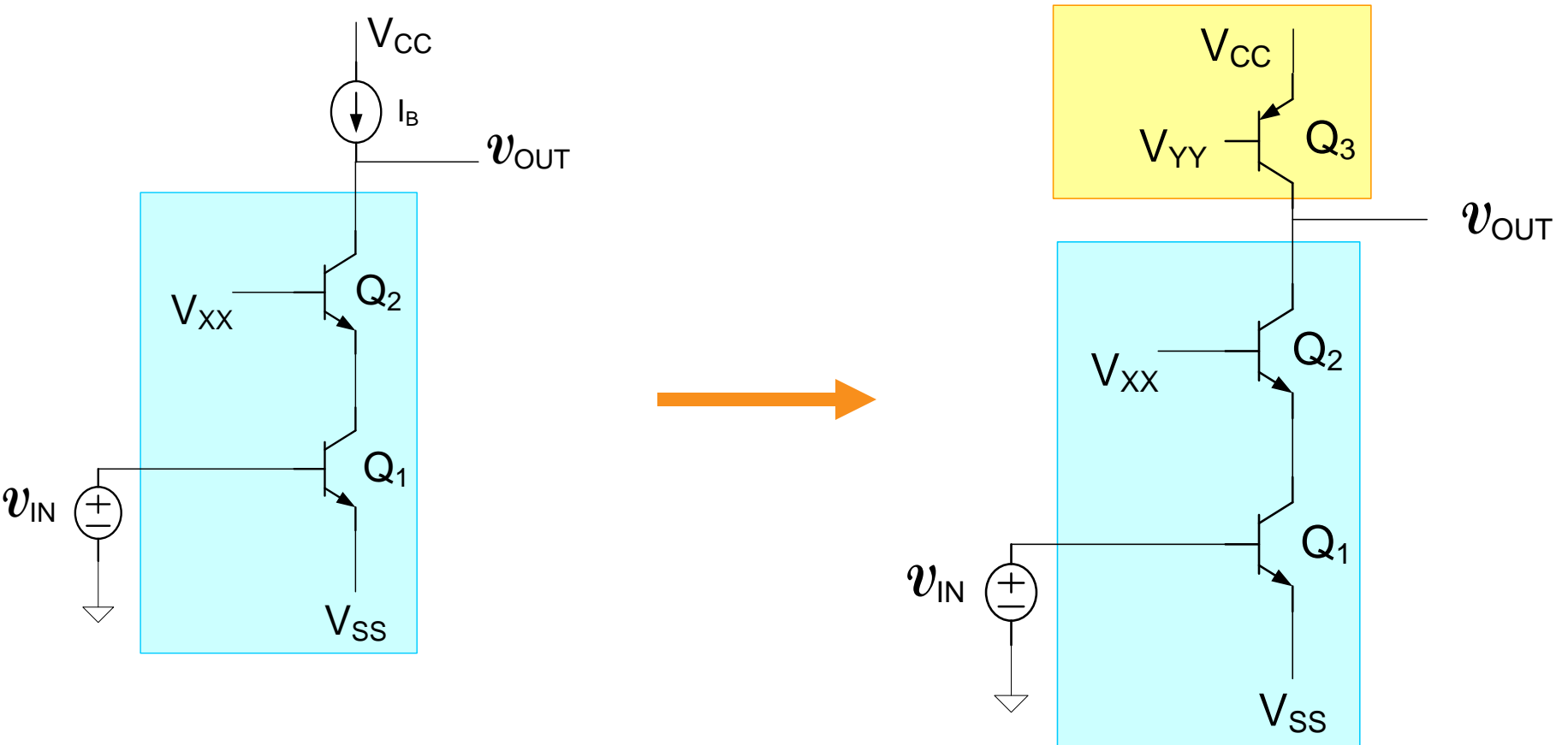
$$A_{V_{CC}} \cong - \left[ \frac{g_{m1}}{g_{o1}} \right] \beta = \left[ \frac{2V_{AF}}{V_t} \right] \beta = [-8000]100$$

$$A_{V_{CC}} \cong -800,000$$

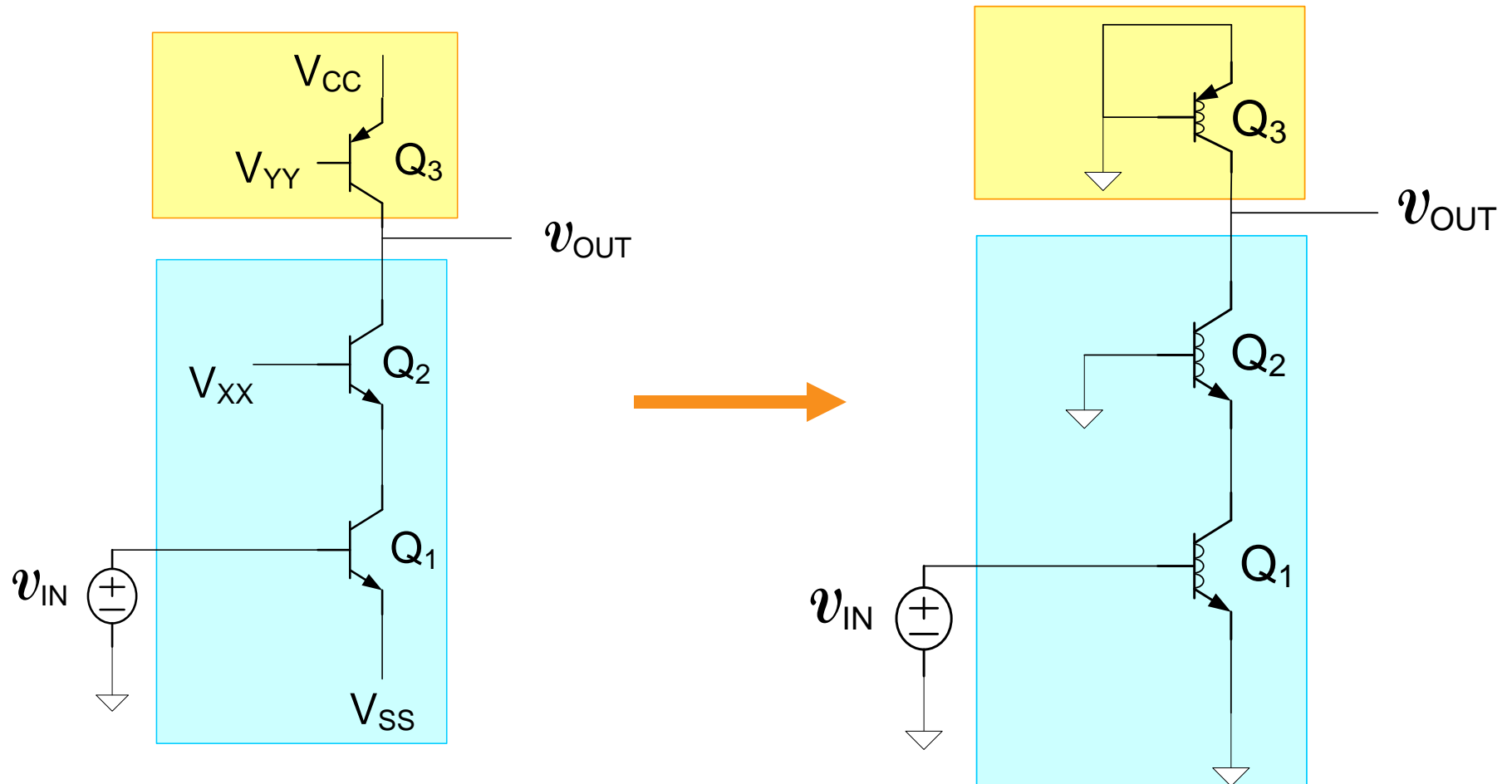
**This gain is very large and only requires two transistors!**

**What happens to the gain if a transistor-level current source is used for  $I_B$ ?**

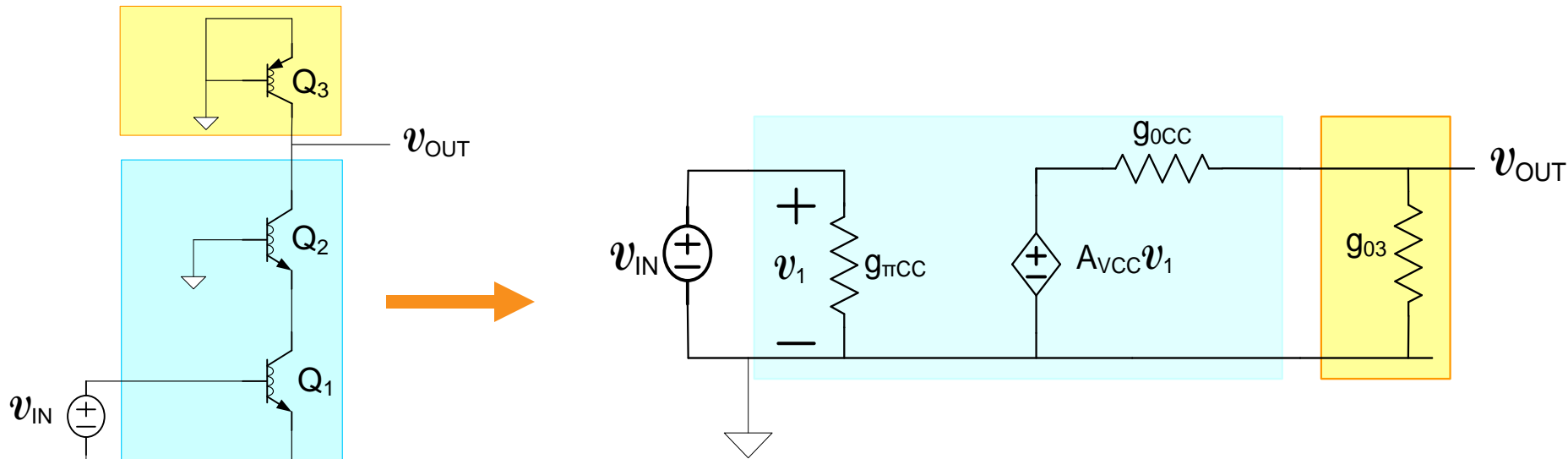
# Cascode Configuration



# Cascode Configuration



# High-gain amplifier comparisons



It thus follows that

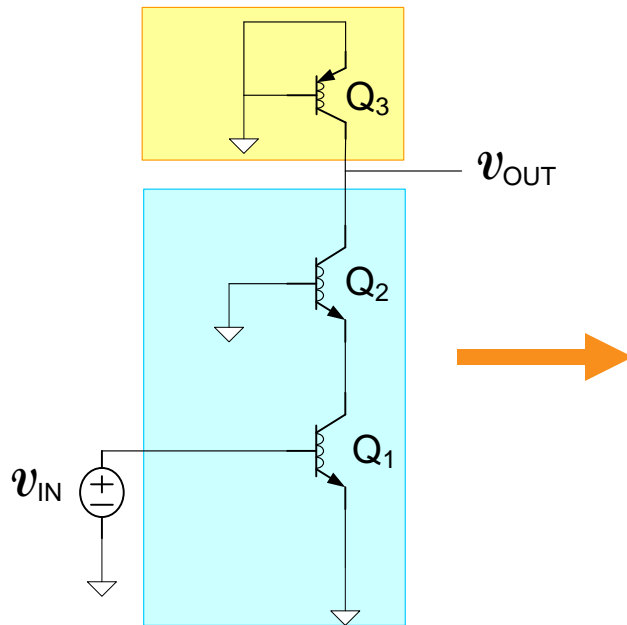
$$A_V = A_{VCC} \left[ \frac{g_{0CC}}{g_{03} + g_{0CC}} \right]$$

But  $g_{0CC} \simeq g_{03}/\beta$

$$A_V \simeq A_{VCC} \left[ \frac{g_{0CC}}{g_{03}} \right] \simeq \frac{A_{VCC}}{\beta}$$

**This is a dramatic reduction in gain compared to what the ideal current source biasing provided**

# Cascode Configuration



$$A_V \cong A_{VCC} \left[ \frac{g_{0CC}}{g_{03}} \right] \cong \frac{A_{VCC}}{\beta}$$

But recall

$$A_{VCC} \cong - \left[ \frac{g_{m1}}{g_{01}} \right] \beta$$

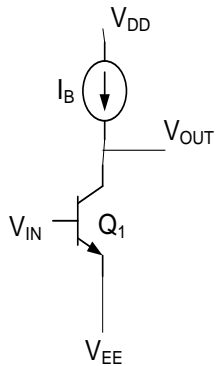
Thus

$$A_V \cong - \left[ \frac{g_{m1}}{g_{01}} \right]$$

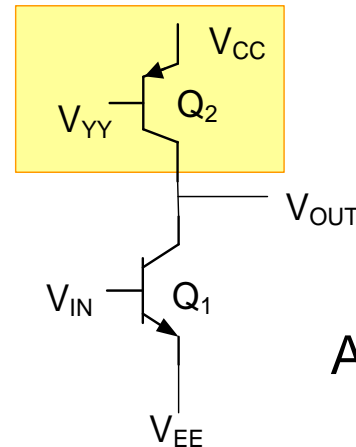
$$A_V \cong - \left[ \frac{I_{CQ} / V_t}{I_{CQ} / V_{AF}} \right] = - \left[ \frac{V_{AF}}{V_t} \right] \cong -8000$$

- This is still a factor of 2 better than that of the CE amplifier with transistor current source  $\left( A_{VCE} \cong - \left[ \frac{g_{m1}}{2g_{01}} \right] \right)$
- It only requires one additional transistor
- But its not nearly as good as the gain the cascode circuit seemed to provide

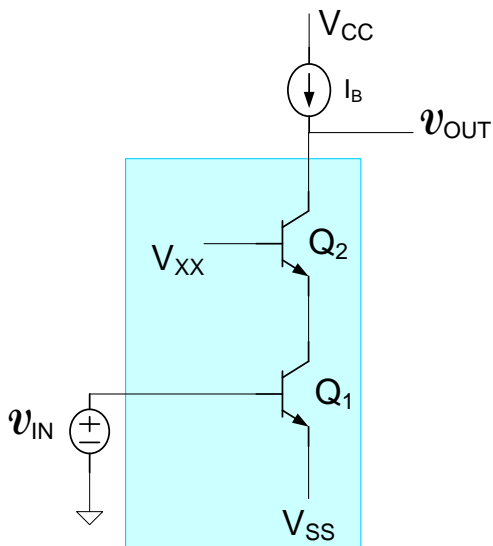
# Cascode Configuration Comparisons



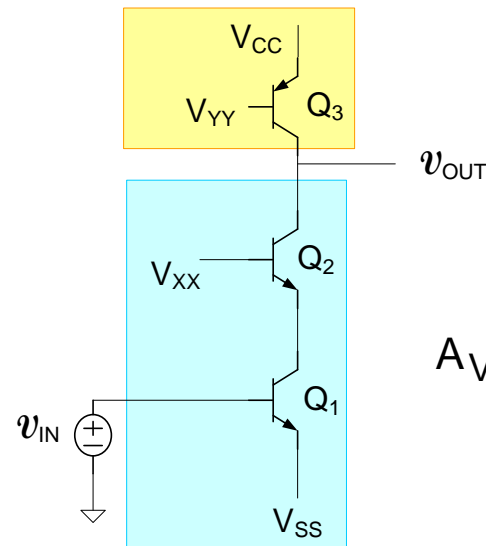
$$A_V = \frac{-g_m}{g_0}$$



$$A_V \cong \frac{-g_{m1}}{g_{01} + g_{02}} = \frac{-g_{m1}}{2g_{01}}$$



$$A_V \cong -\left[\frac{g_{m1}}{g_{01}}\right]\beta$$



$$A_V \cong -\left[\frac{g_{m1}}{\frac{g_{01}}{\beta} + g_{03}}\right] \cong -\left[\frac{g_{m1}}{g_{03}}\right]$$

**Gain limited by output impedance of current source !!**

**Can we design a better current source?**

**In particular, one with a higher output impedance?**

# Better current sources

Need a higher output impedance than  $g_o$



The output impedance of the cascode circuit itself was very large !

$$g_{oCC} \cong \frac{g_{o1}}{\beta}$$

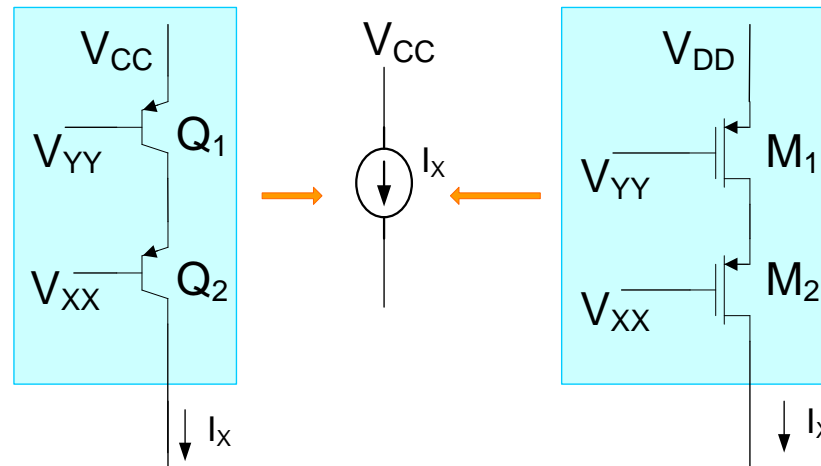
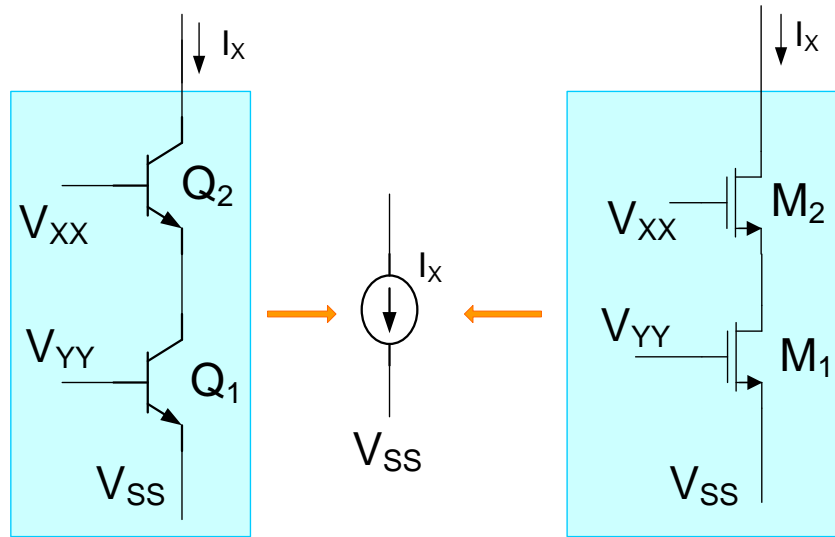
Can a current source be built with the cascode circuit ?



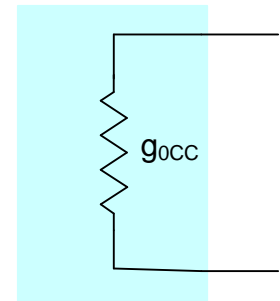
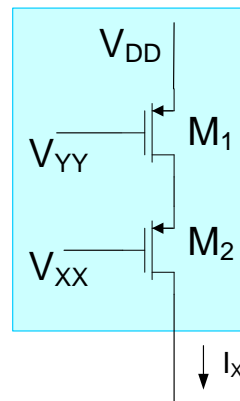
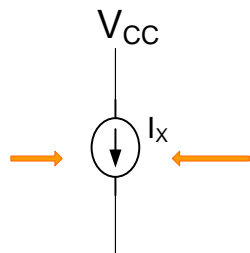
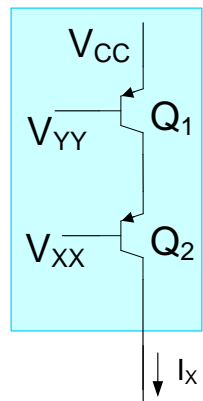
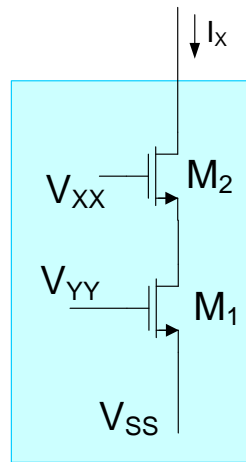
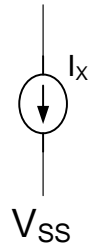
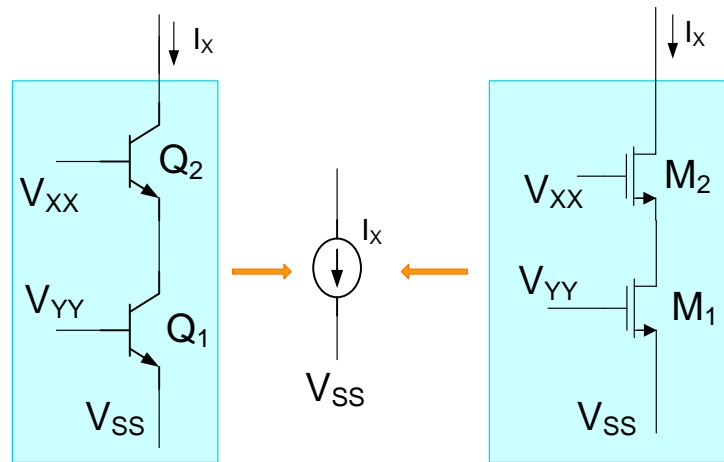
# Cascode current sources



**Discuss**



# Cascode current sources

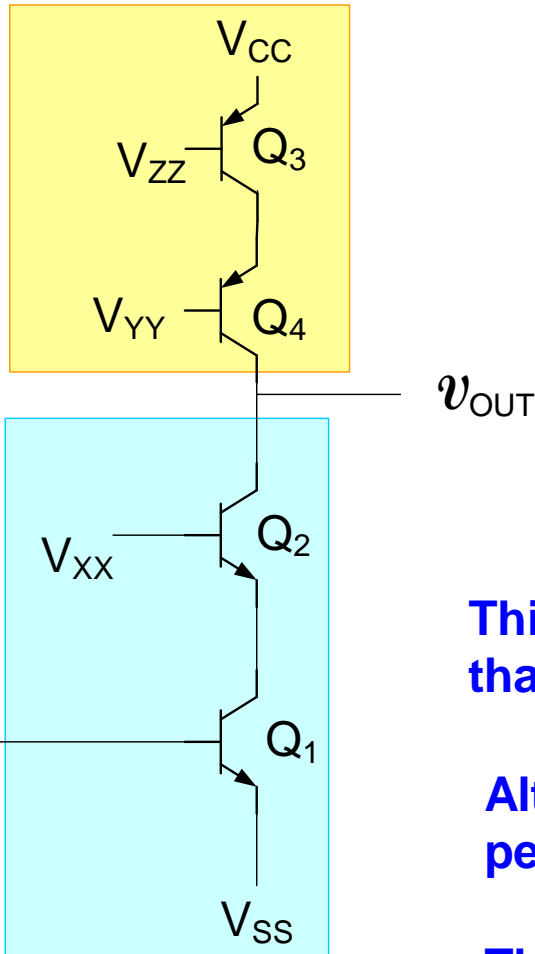


All have the same small-signal model

$$g_{0CC} = \left[ \frac{g_{02}(g_{01} + g_{\pi 2})}{g_{01} + g_{02} + g_{\pi 2} + g_{m2}} \right]$$

# Cascode Configuration

Discuss



$$A_V = - \left[ \frac{g_{m1}}{g_{01}} \right] \frac{\beta}{2}$$

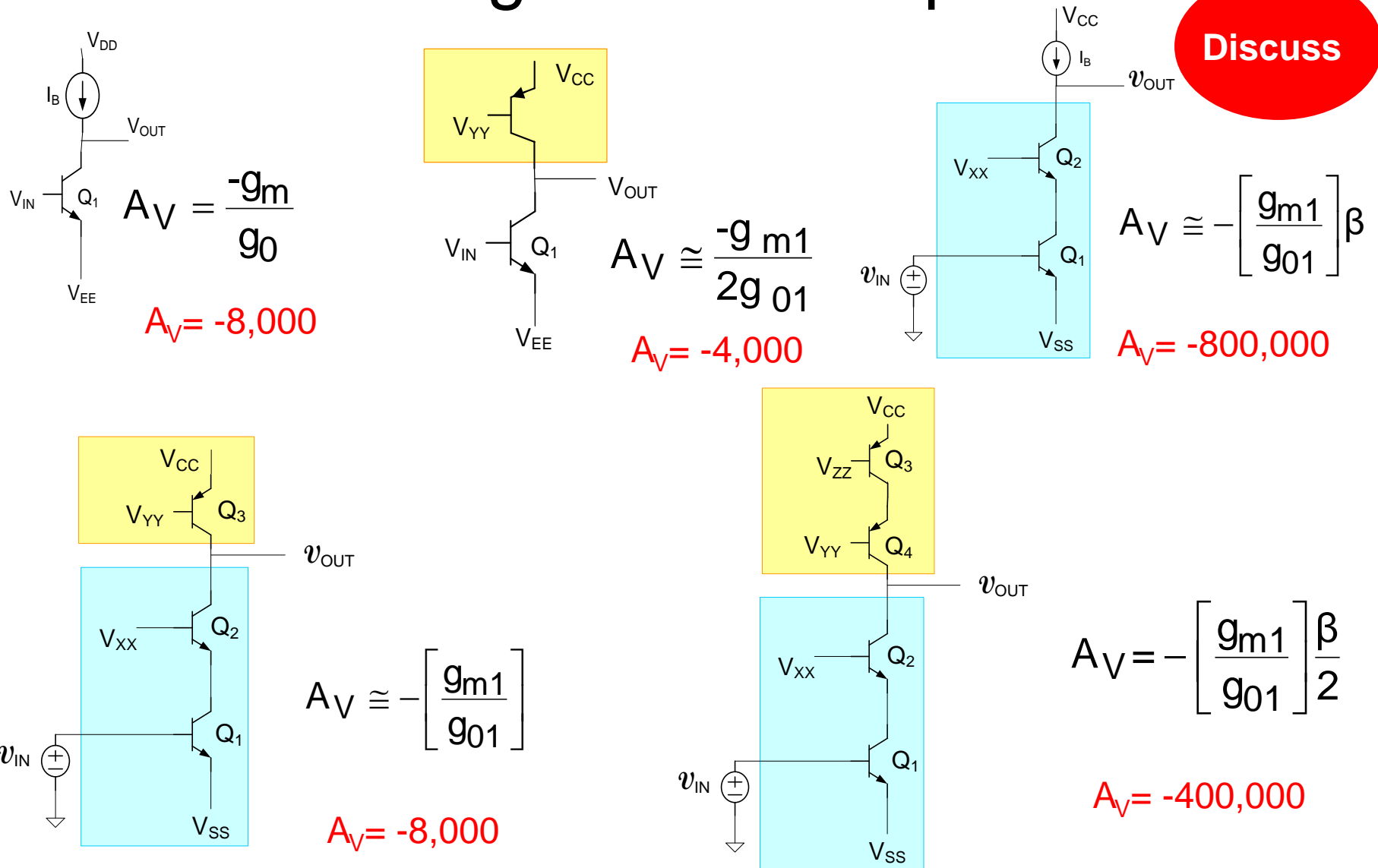
$$A_V = - [8000] \frac{100}{2} \cong -400,000$$

**This gain is very large and is a factor of 2 below that obtained with an ideal current source biasing**

**Although the factor of 2 is not desired, the performance of this circuit is still very good**

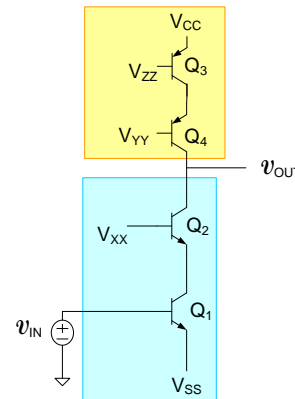
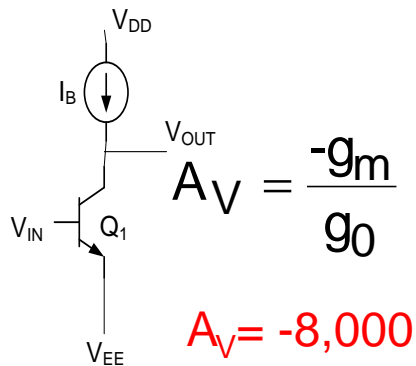
**This factor of 2 gain reduction is that same as was observed for the CE amplifier when a transistor-level current source was used**

# Cascode Configuration Comparisons



Can we use more cascoding to further increase the gain?

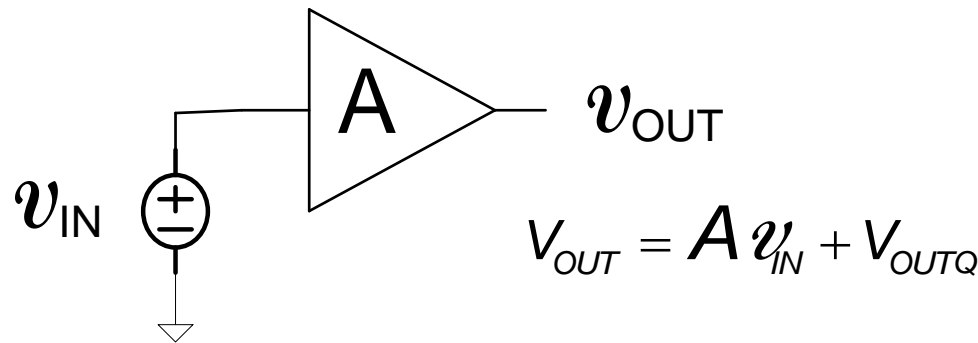
# High Gain Amplifiers Seldom Used Open Loop



$$A_V = - \left[ \frac{g_{m1}}{g_{o1}} \right] \frac{\beta}{2}$$

$A_V = -400,000$

**Discuss**

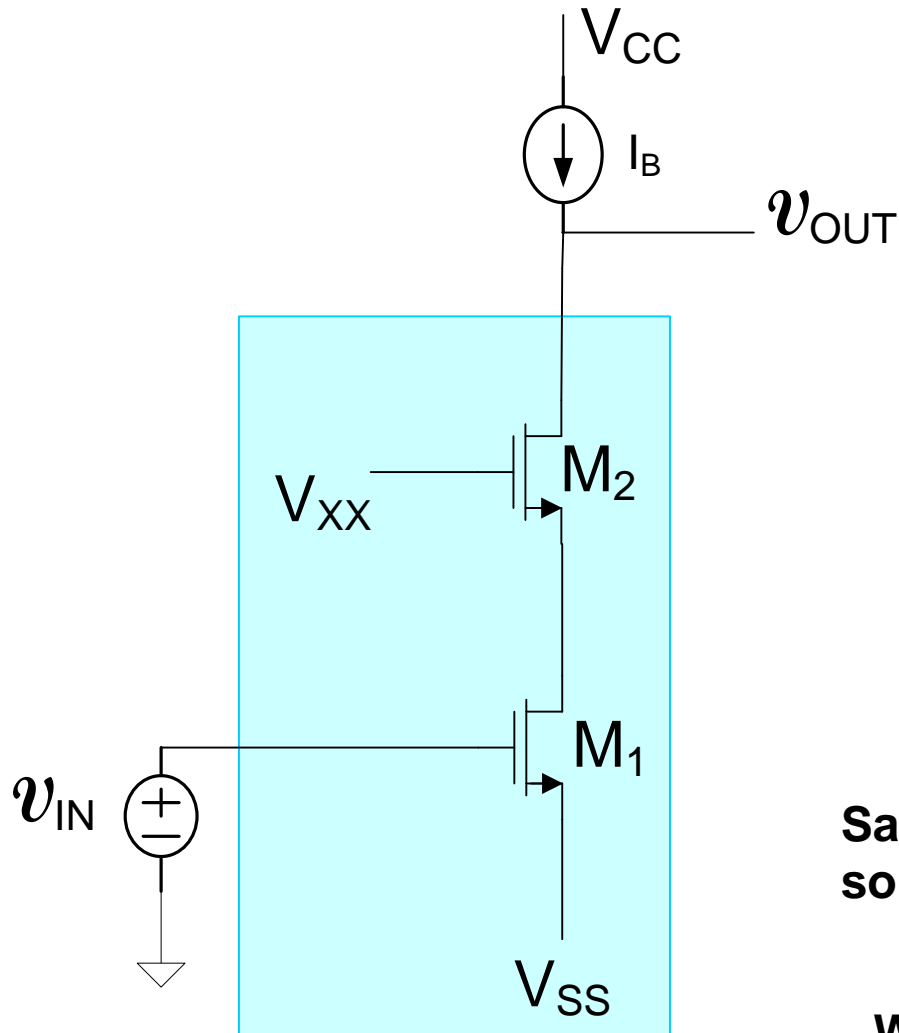


If  $A_V = -400,000$  and  $V_{IN}$  increases by 1mV, what would happen at the output?

$V_{OUT}$  would decrease by  $400,000 \times 1\text{mV} = -400\text{V}$

# The Cascode Amplifier (consider n-ch MOS version)

Discuss



$$A_{V_{CC}} \cong - \left[ \frac{g_{m1} g_{m2}}{g_{o1} g_{o2}} \right]$$

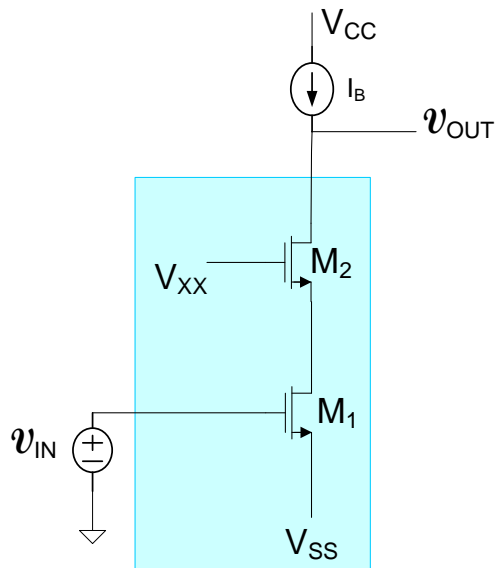
$$g_{oCC} \cong \left[ \frac{g_{o1} g_{o2}}{g_{m2}} \right]$$

Same issues for biasing with current source as for BJT case

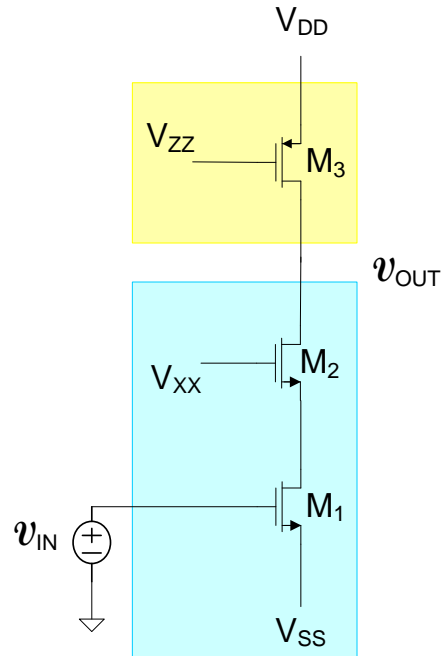
With cascode current source, gain only drops by a factor of 2

# The Cascode Amplifier (consider n-ch MOS version)

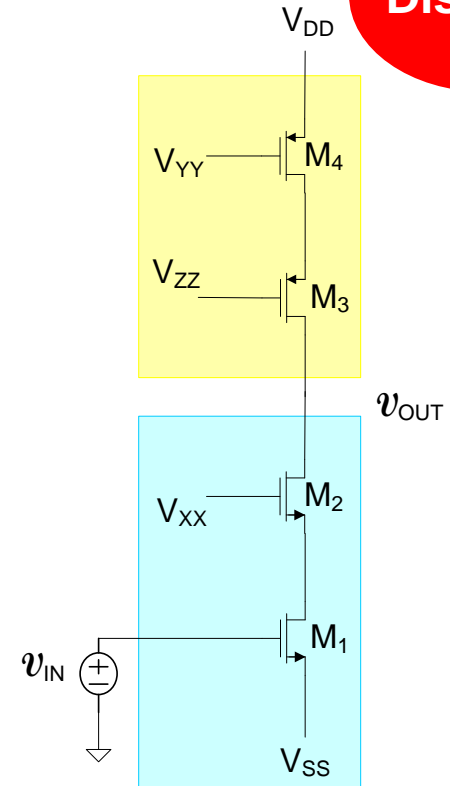
**Discuss**



$$A_{VCC} \cong - \left[ \frac{g_{m1}g_{m2}}{g_{o1}g_{o2}} \right]$$



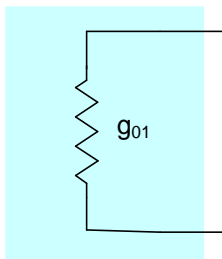
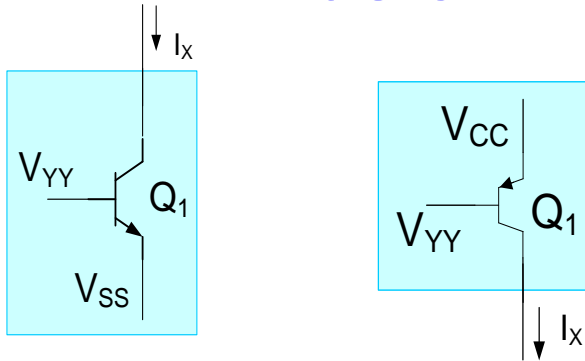
$$A_{VCC} \cong - \left[ \frac{g_{m1}}{g_{o1}} \right]$$



$$A_{VCC} \cong - \frac{1}{2} \left[ \frac{g_{m1}g_{m2}}{g_{o1}g_{o2}} \right]$$

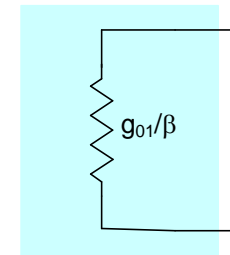
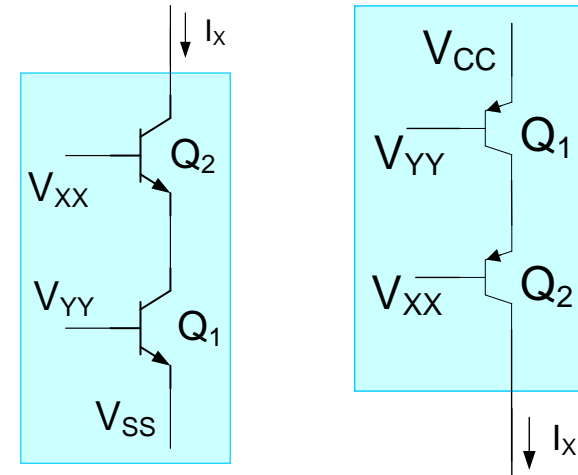
# Current Source Summary (BJT)

## Basic



$$g_0 \cong g_{01}$$

## Cascode

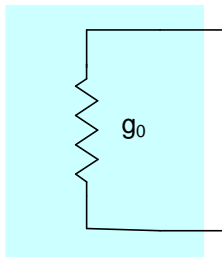
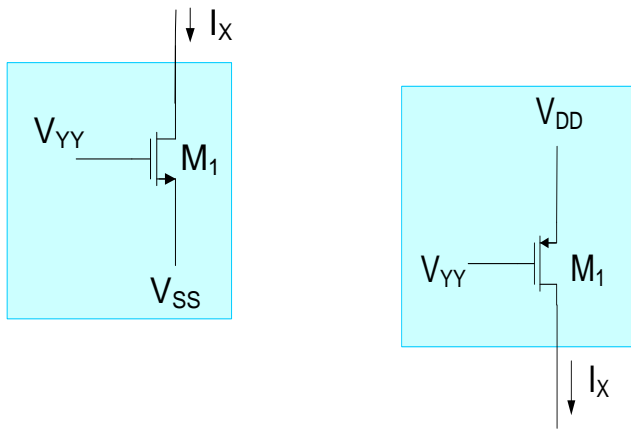


$$g_{0CC} \cong \frac{g_{01}}{\beta}$$



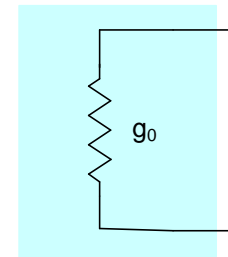
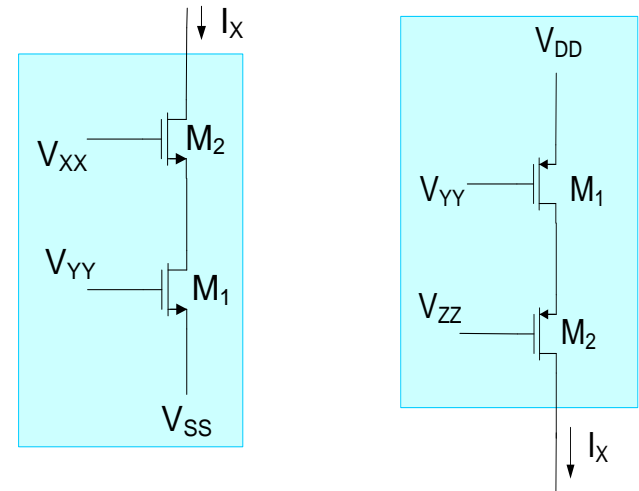
# Current Source Summary (MOS)

## Basic



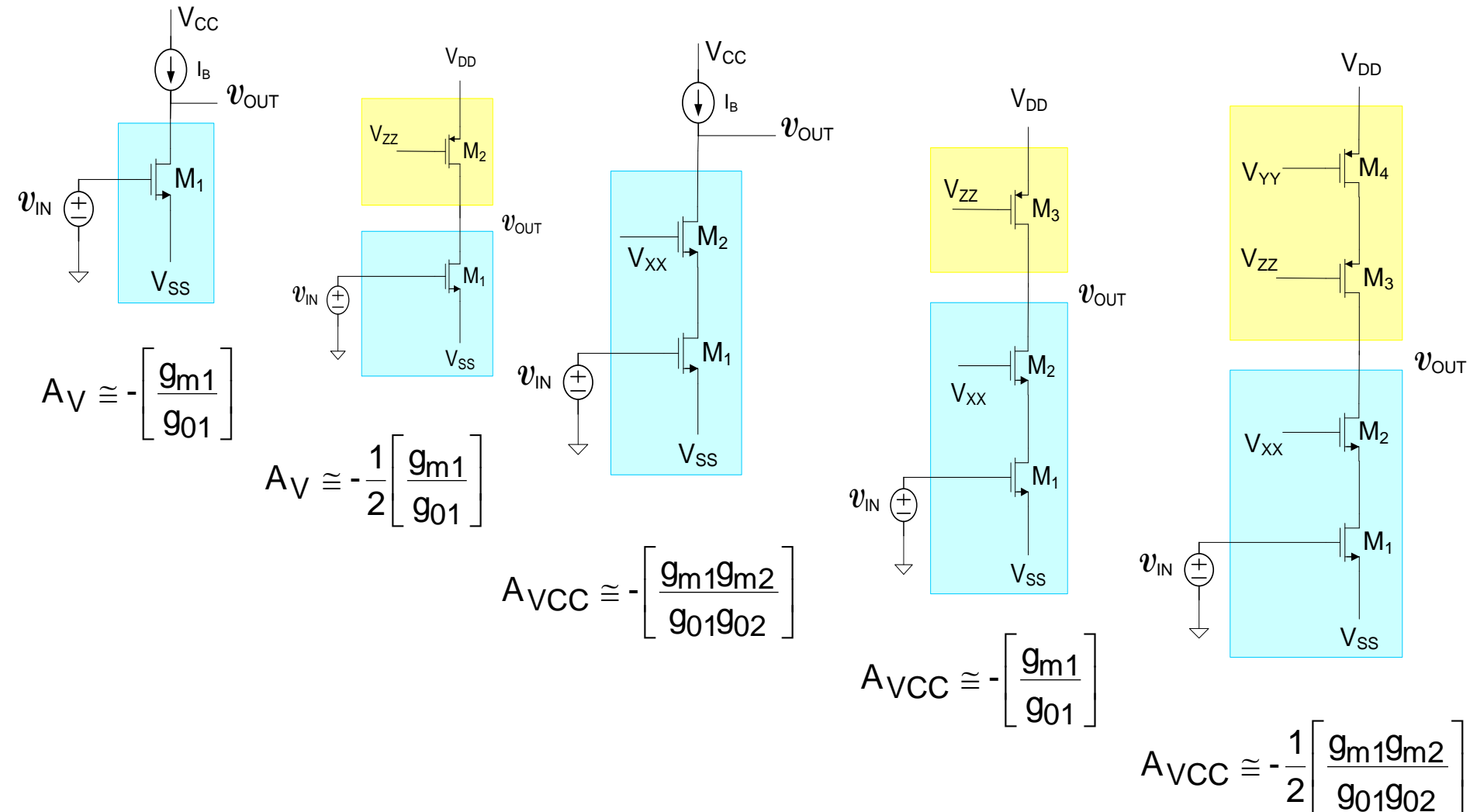
$$g_0 \cong g_{01}$$

## Cascode

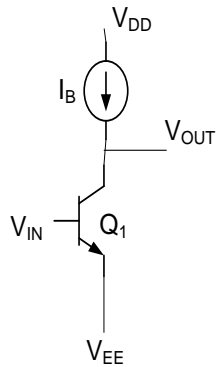


$$g_0 \cong g_{01} \frac{g_{02}}{g_{m2}}$$

# High Gain Amplifier Comparisons ( n-ch MOS)



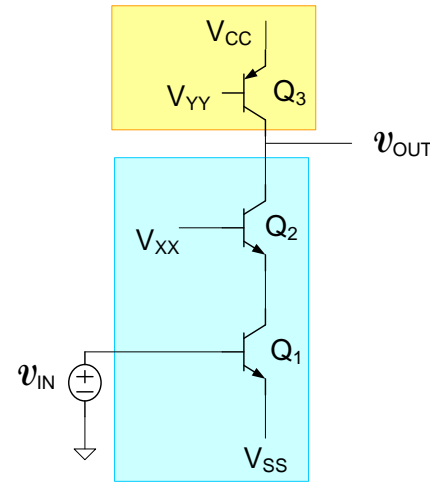
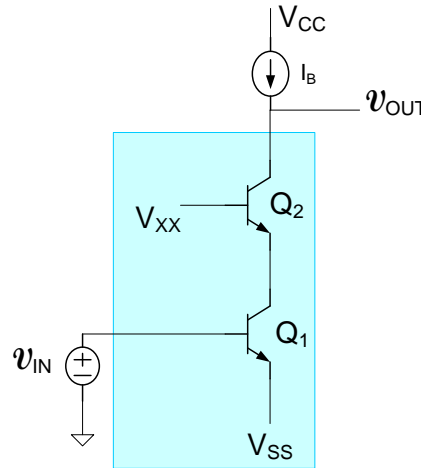
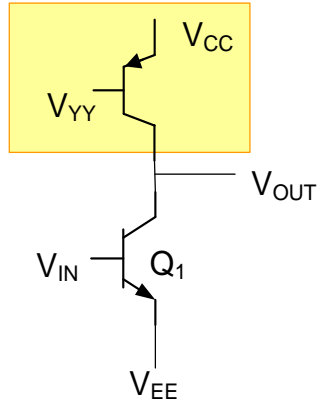
# High Gain Amplifier Comparisons (BJT)



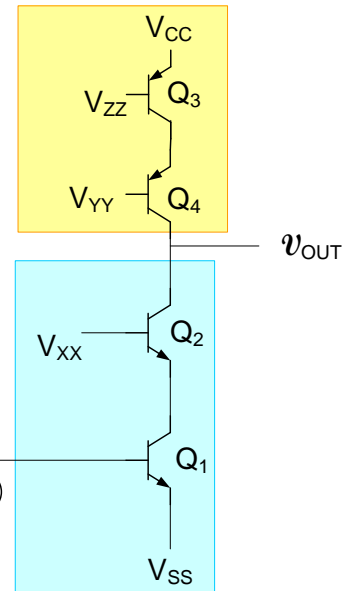
$$A_V = \frac{-g_m}{g_0}$$

$$A_V \cong -\frac{1}{2} \frac{g_{m1}}{g_{01}}$$

$$A_V \cong -\left[ \frac{g_{m1}}{g_{01}} \right] \beta$$



$$A_V \cong -\left[ \frac{g_{m1}}{g_{01}} \right]$$

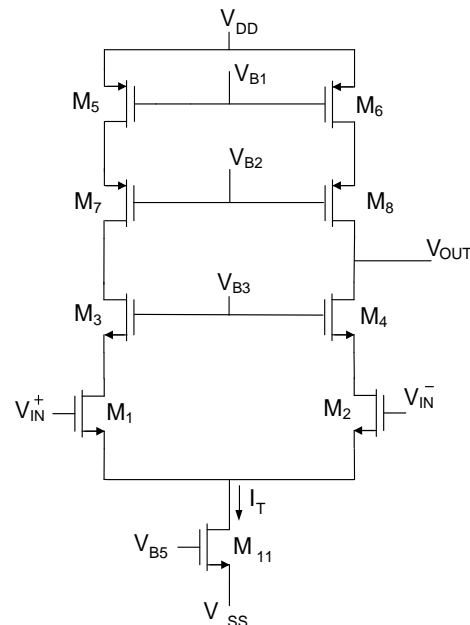


$$A_V = -\left[ \frac{g_{m1}}{g_{01}} \right] \frac{\beta}{2}$$

- Single-ended high-gain amplifiers inherently difficult to bias (because of the high gain)
- Biasing becomes practical when used in differential applications
- These structures are widely used but usually with differential inputs

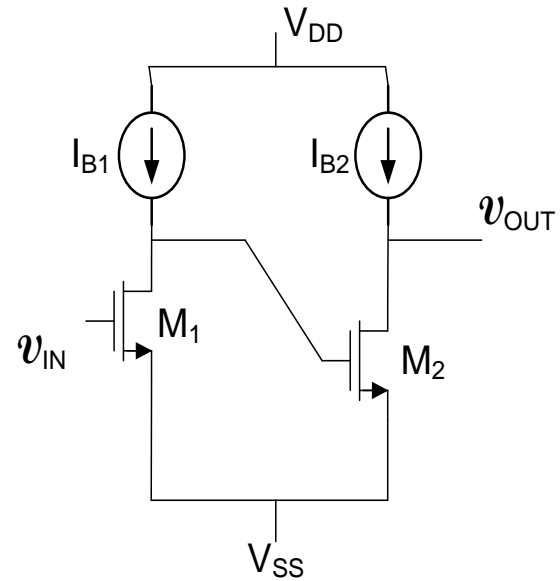
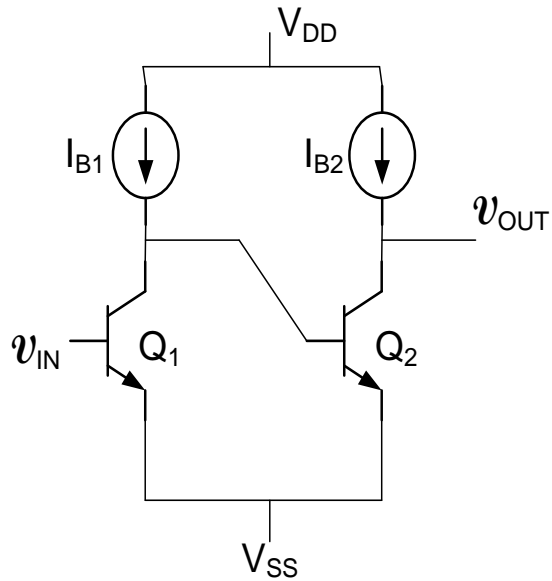
# The Cascode Amplifier

- Operational amplifiers often built with basic cascode configuration
- CMFB used to address the biasing problem
- Usually configured as a differential structure when building op amps
- Have high output impedance (but can be buffered)
- Terms “telescopic cascode”, “folded-cascode”, and “regulated cascode” often refer to op amps based upon the cascode configuration



**Telescopic Cascode Op Amp**  
(CMFB feedback biasing not shown)

# Cascade Configurations

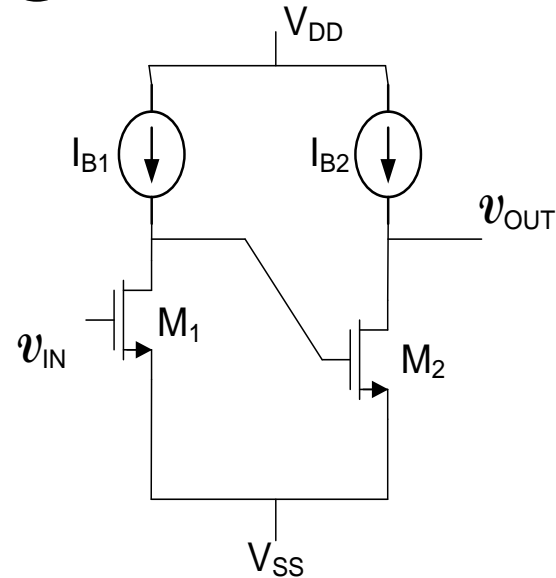
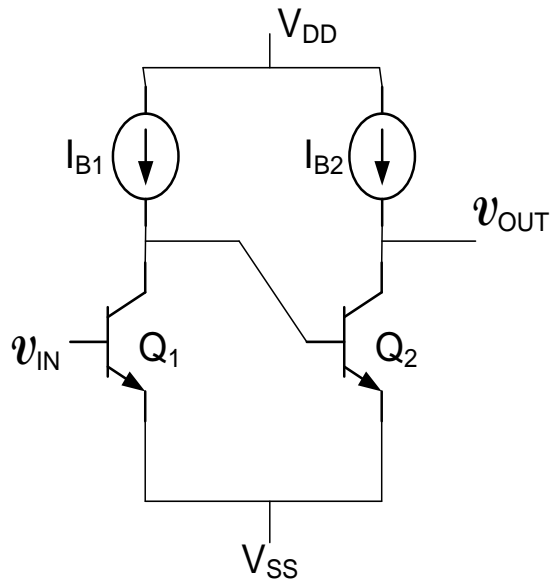


**Two-stage CE:CE or CS:CS Cascade**

$$A_{V_{CB}} = ?$$

$$A_{V_{CM}} = ?$$

# Cascade Configurations



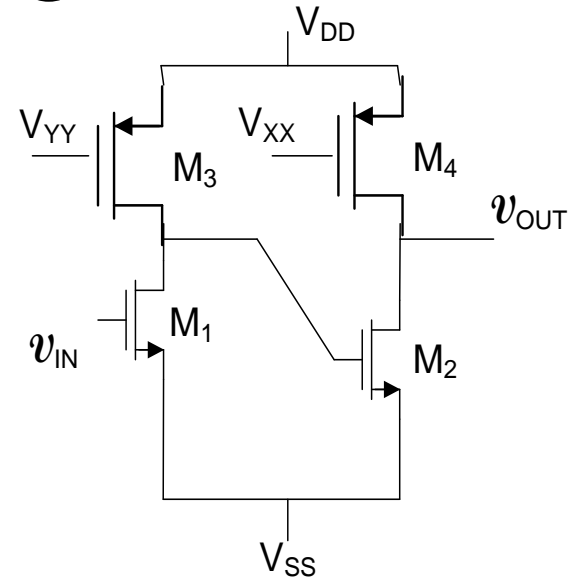
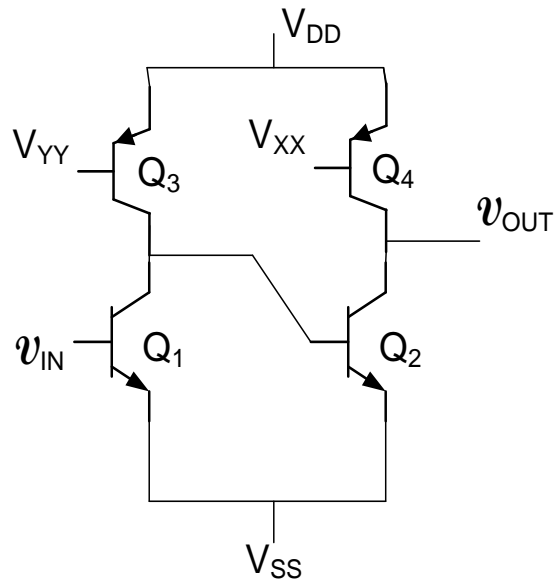
## Two-stage CE:CE or CS:CS Cascade

$$A_{VCB} \cong \left[ \frac{-g_{m1}}{g_{o1} + g_{\pi 2}} \right] \left[ \frac{-g_{m2}}{g_{o2}} \right] \cong \frac{g_{m1} g_{m2}}{g_{\pi 2} g_{o2}} = \beta \frac{g_{m1}}{g_{o2}}$$

$$A_{VCM} = \left[ \frac{-g_{m1}}{g_{o1}} \right] \left[ \frac{-g_{m2}}{g_{o2}} \right] = \frac{g_{m1} g_{m2}}{g_{o1} g_{o2}}$$

- **Significant increase in gain**
- **Gain is noninverting**
- **Comparable to that obtained with the cascode but noninverting**

# Cascade Configurations



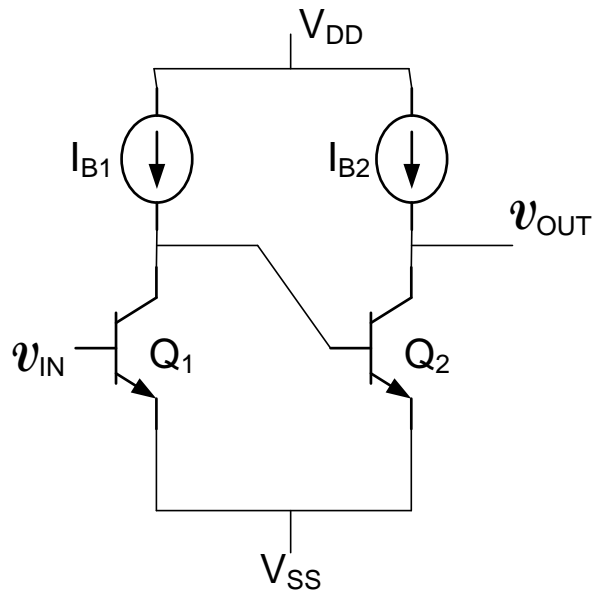
## Two-stage CE:CE or CS:CS Cascade

$$A_{VCB} \cong \left[ \frac{-g_{m1}}{g_{01} + g_{03} + g_{\pi 2}} \right] \left[ \frac{-g_{m2}}{g_{02} + g_{04}} \right] \cong \frac{g_{m1} g_{m2}}{2g_{\pi 2} g_{02}} = \beta \frac{g_{m1}}{2g_{02}}$$

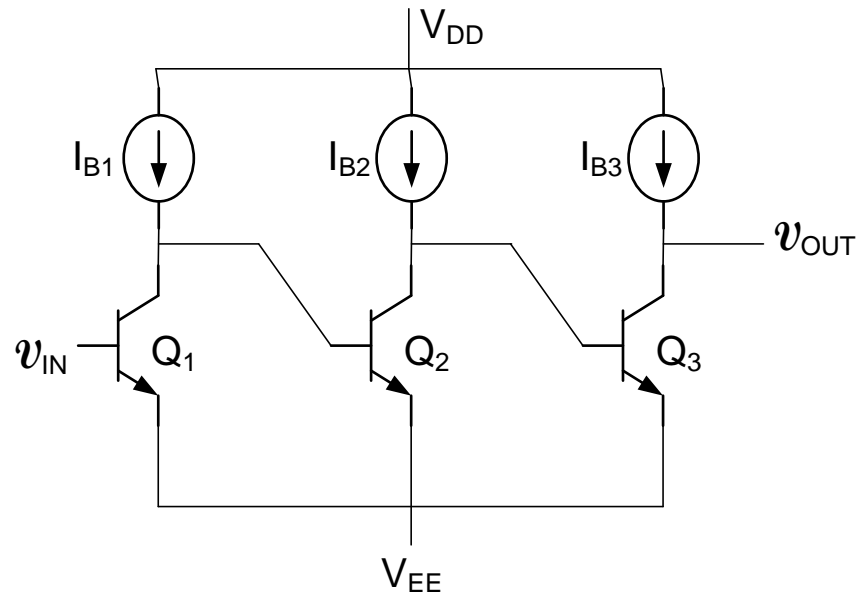
$$A_{VCM} = \left[ \frac{-g_{m1}}{g_{01} + g_{03}} \right] \left[ \frac{-g_{m2}}{g_{02} + g_{04}} \right] = \frac{g_{m1} g_{m2}}{4g_{01} g_{02}}$$

**Note factor of 2 and 4 reduction in gain due to actual current source bias**

# Cascade Configurations



**Two-stage CE Cascade**

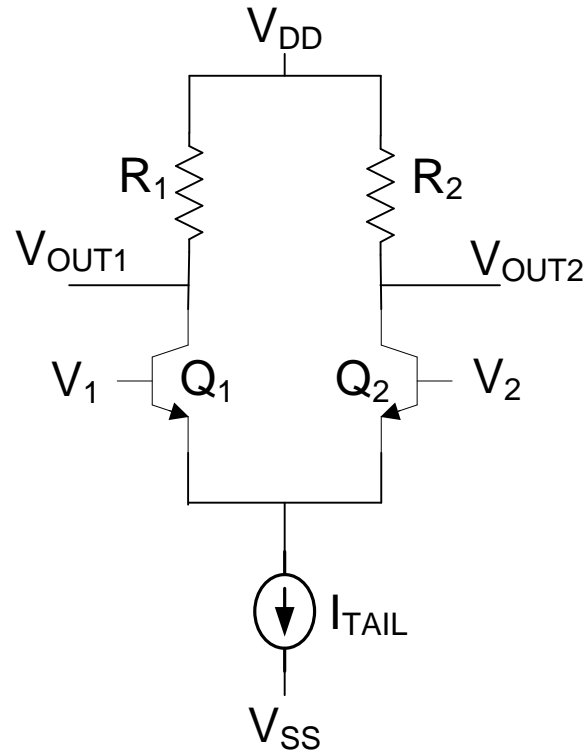


**Three-stage CE Cascade**

- Large gains can be obtained by cascading
- Gains are multiplicative (when loading is included)
- Large gains used to build “Op Amps” and feedback used to control gain value
- Some attention is needed for biasing but it is manageable
- Minor variant of the two-stage cascade often used to built Op Amps
- Compensation of two-stage cascade needed if feedback is applied to maintain stability
- For many years three or more stages were seldom cascaded because of challenges in compensation to maintain stability though recently some industrial adoptions



# Differential Amplifiers



Basic operational amplifier circuit

# Amplifier Biasing

**Amplifier biasing is that part of the design of a circuit that establishes the desired operating point (or Q-point)**

**Goal is to invariably minimize the impact the biasing circuit has on the small-signal performance of a circuit**

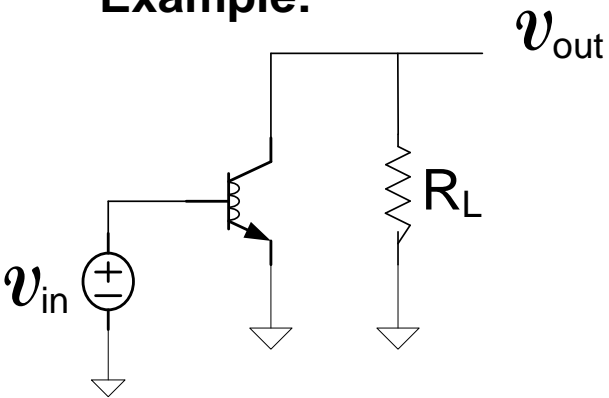
**Usually at most 2 dc power supplies are available and these are often fixed in value by system requirements – this restriction is cost driven**

**Discrete amplifiers invariably involve adding biasing resistors and use capacitor coupling and bypassing**

**Integrated amplifiers often use current sources which can be used in very large numbers and are very inexpensive**

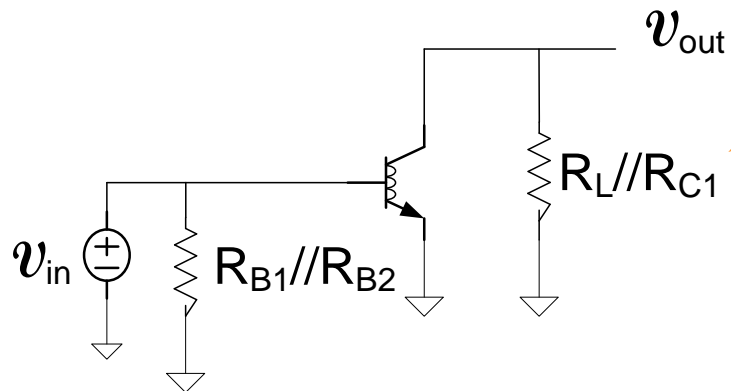
# Amplifier Biasing

**Example:**



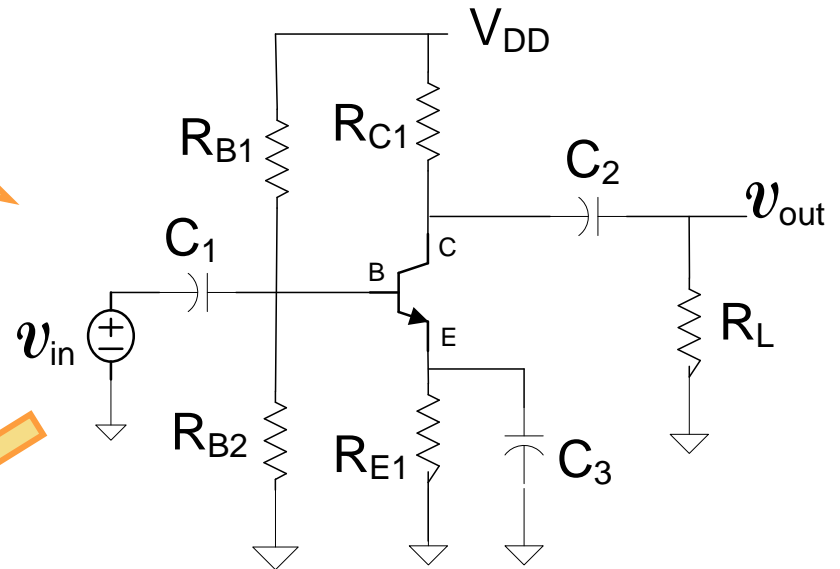
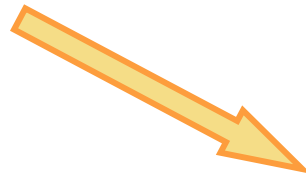
$$A_V = -g_m R_L$$

**Desired small-signal circuit  
Common Emitter Amplifier**

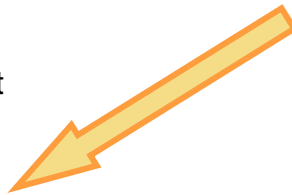


**Actual small-signal circuit**

$$A_V = -g_m (R_L // R_{C1})$$

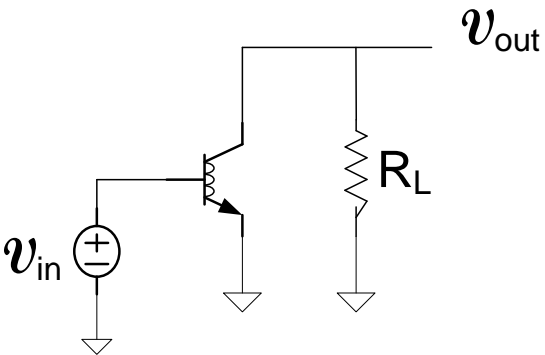


**Biased circuit**



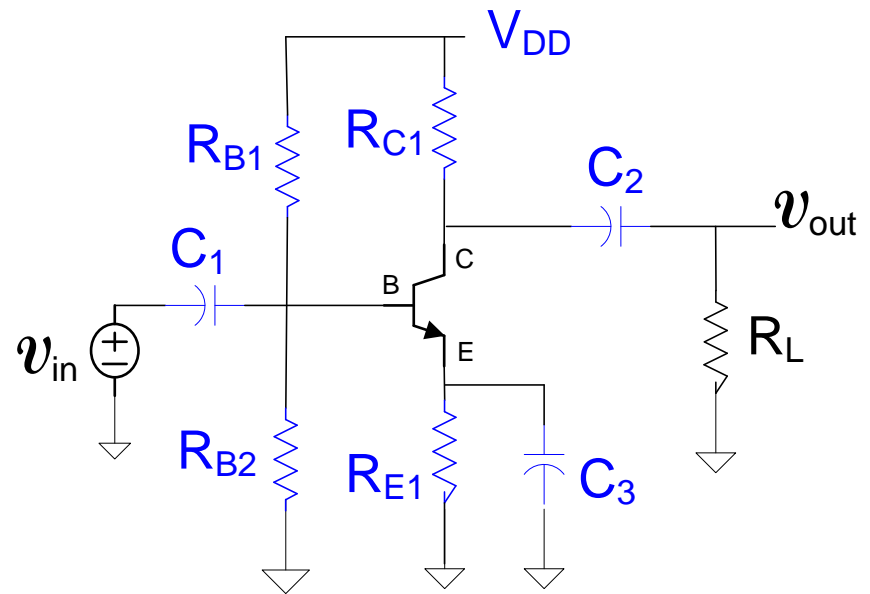
# Amplifier Biasing

Example:



**Desired small-signal circuit**  
**Common Emitter Amplifier**

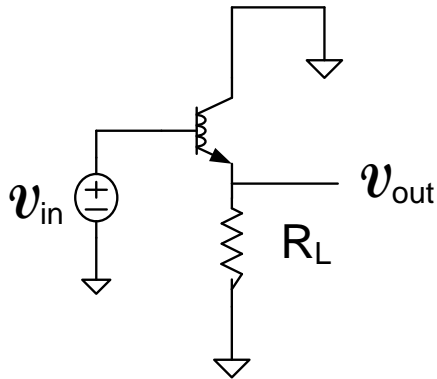
*Biasing components  
shown in blue*



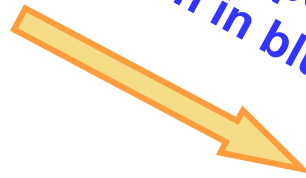
**Biased small-signal circuit**

# Amplifier Biasing

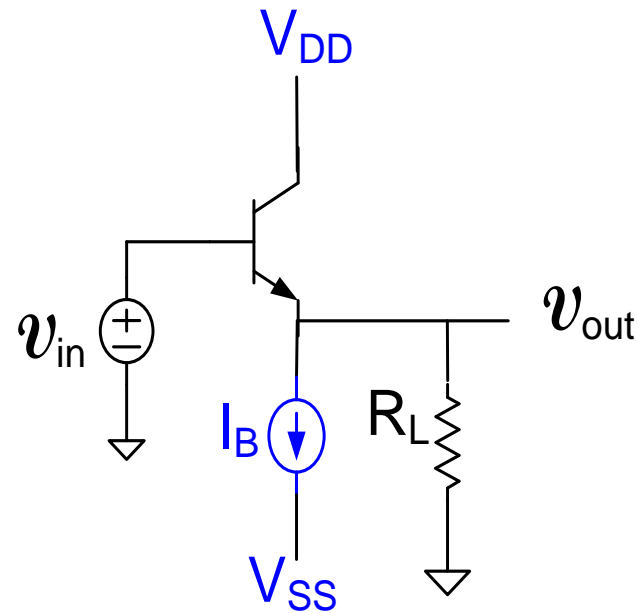
Example:



Biasing components  
shown in blue



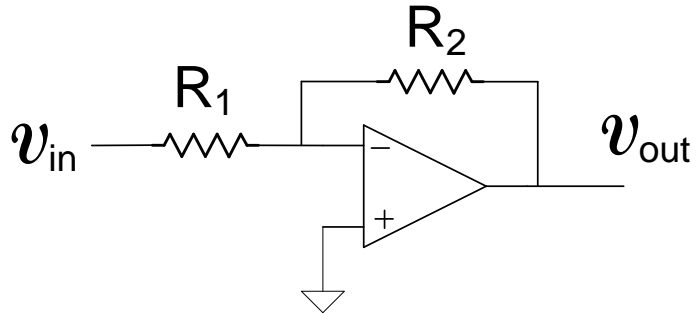
Desired small-signal circuit  
Common Collector Amplifier



Biased circuit

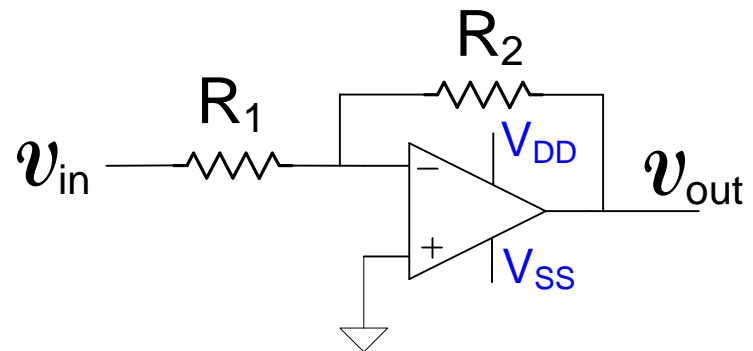
# Amplifier Biasing

Example:



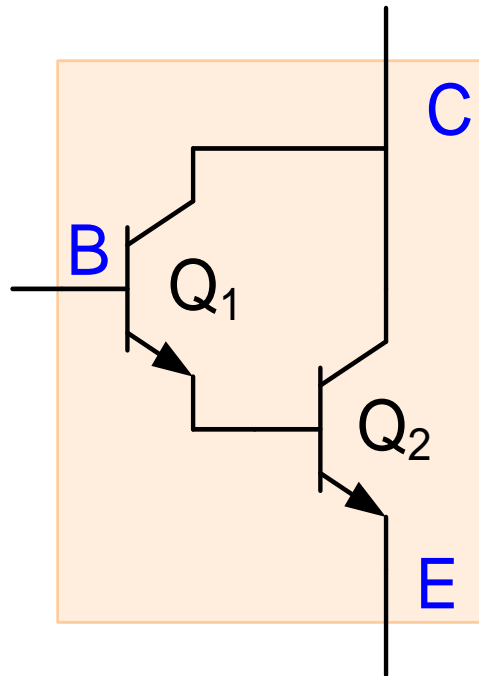
**Desired small-signal circuit**  
**Inverting Feedback Amplifier**

Biased components  
shown in blue

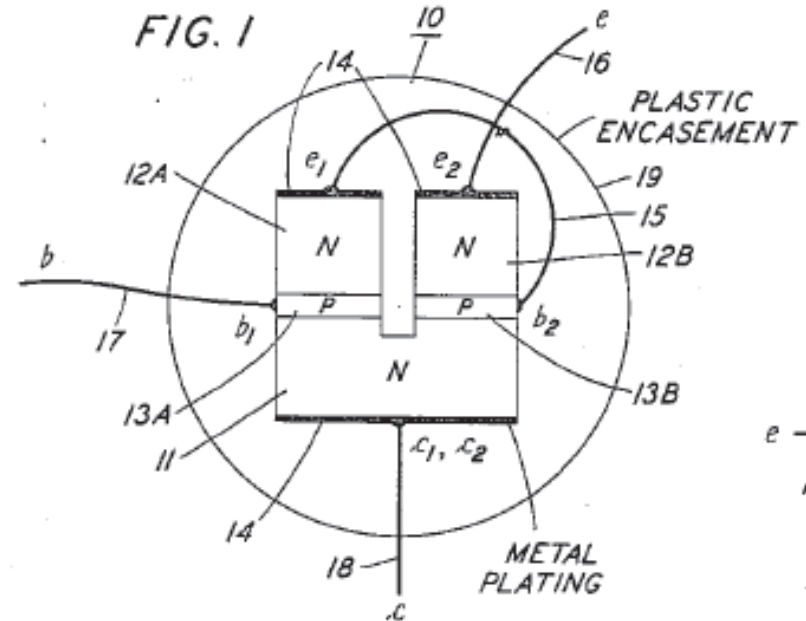


**Biased circuit**

# Other Basic Configurations



**Darlington Configuration**



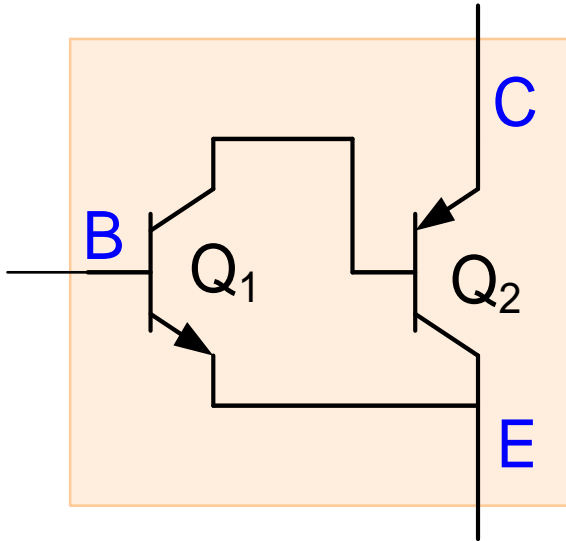
S. DARLINGTON  
SEMICONDUCTOR SIGNAL TRANSLATING DEVICE

2,663,806

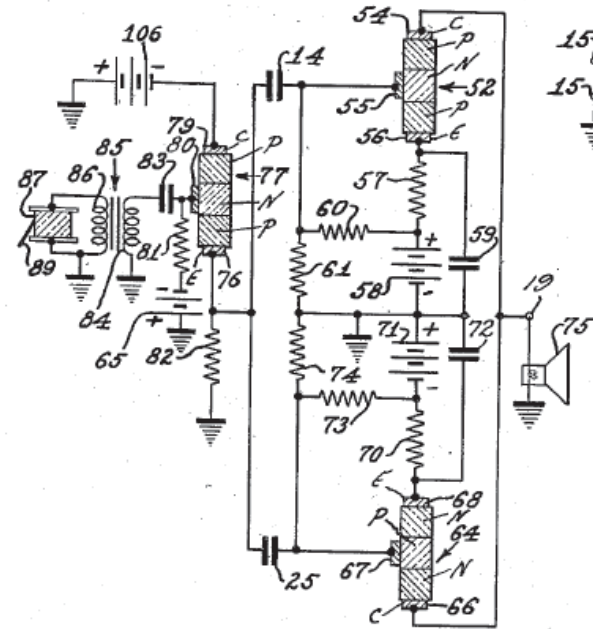
Filed May 9, 1952

- Current gain is approximately  $\beta^2$
- Two diode drop between  $B_{eff}$  and  $E_{eff}$

# Other Basic Configurations



**Sziklai Pair**



**FIG. 3.**

May 7, 1957

G. C. SZIKLAI

2,791,644

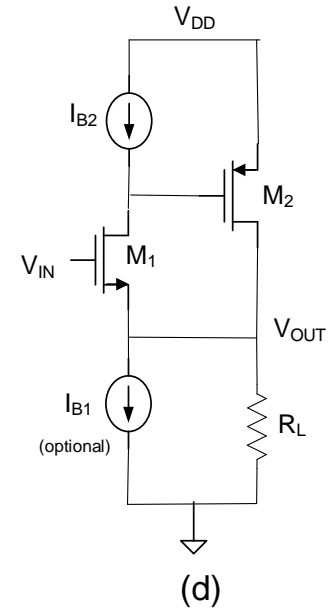
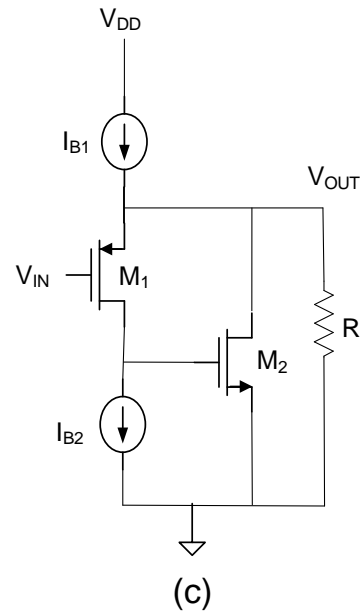
PUSH-PULL AMPLIFIER WITH COMPLEMENTARY TYPE TRANSISTORS

Filed Nov. 7, 1952

- Same basic structure as Darlington Pair
- Current gain is approximately  $\beta_n \beta_p$
- Current gain will not be as large when  $\beta_p < \beta_n$
- Only one diode drop between  $B_{eff}$  and  $E_{eff}$

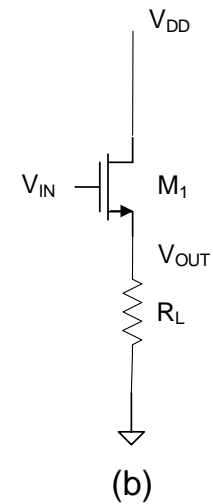
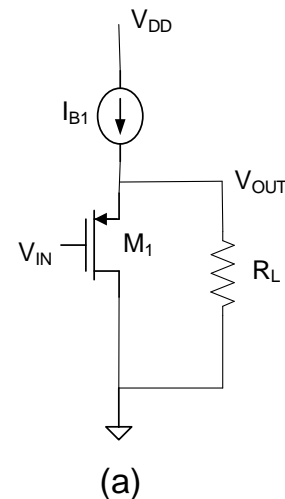


# Other Basic Configurations



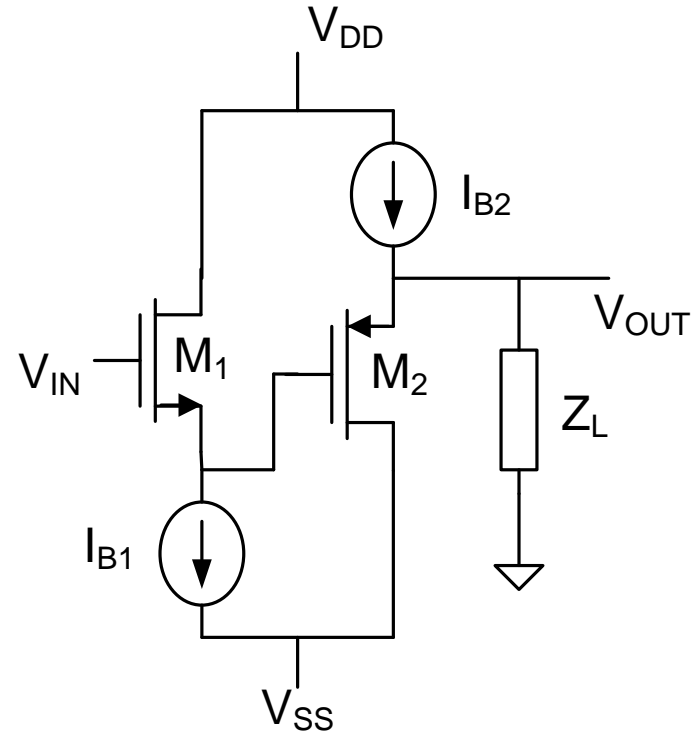
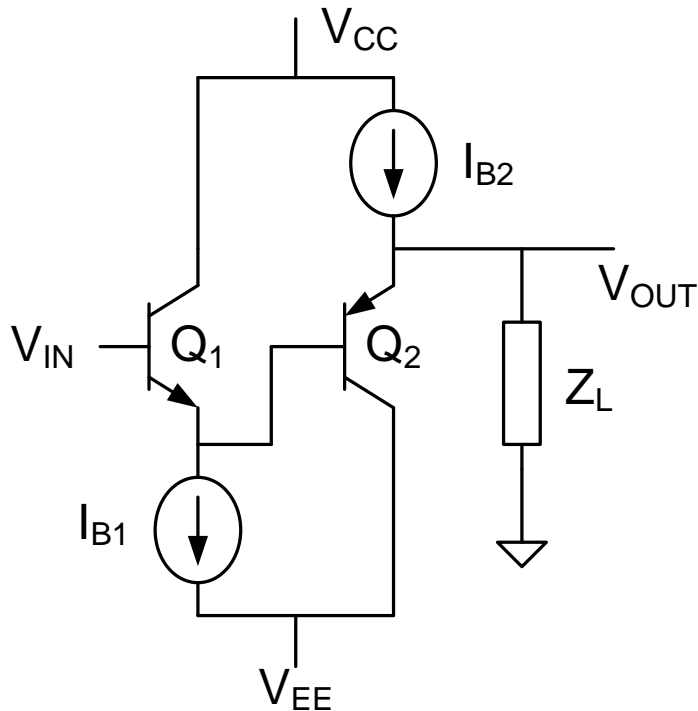
## Buffer and Super Buffer

- Voltage shift varies with  $V_{IN}$  in buffer
- Current through shift transistor is constant for Super Buffer as  $V_{IN}$  changes so voltage shift does not change with  $V_{IN}$
- Same nominal voltage shift



# Other Basic Configurations

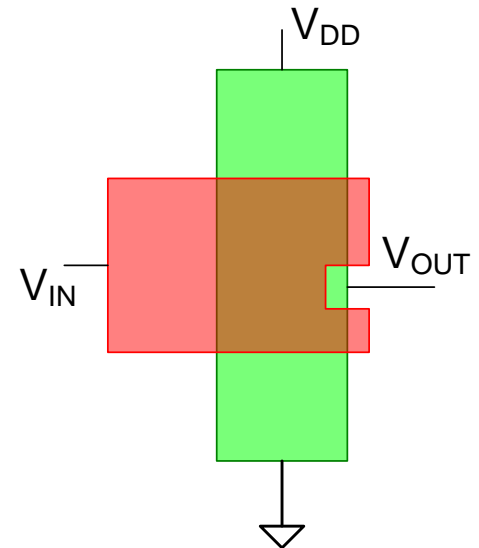
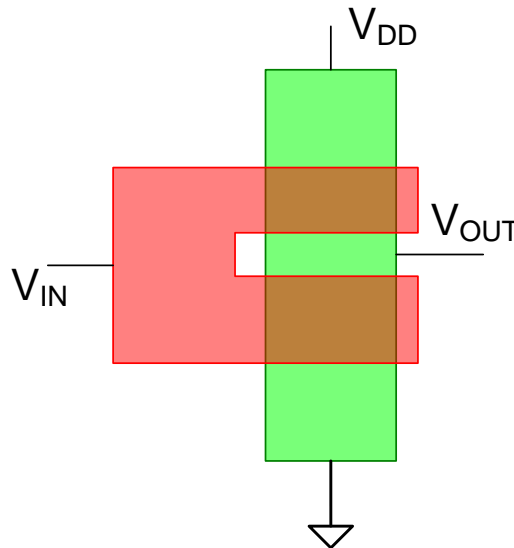
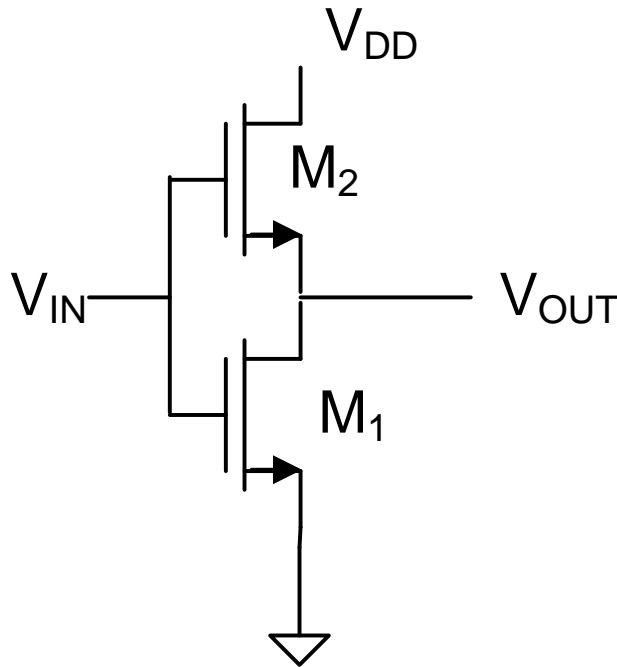
## Low offset buffers



- **Actually a CC-CC or a CD-CD cascade**
- **Significant drop in offset between input and output**
- **Biasing with DC current sources**
- **Can Add Super Buffer to Output**

# Other Basic Configurations

## Voltage Attenuator



- Attenuation factor is quite accurate (Determined by geometry)
- Infinite input impedance
- $M_1$  in triode,  $M_2$  in saturation
- Actually can be a channel-tapped structure

End of Lecture 35